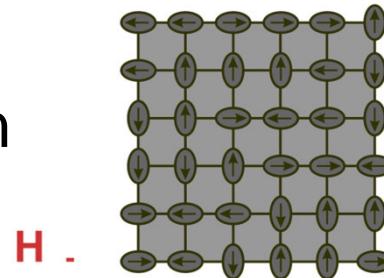
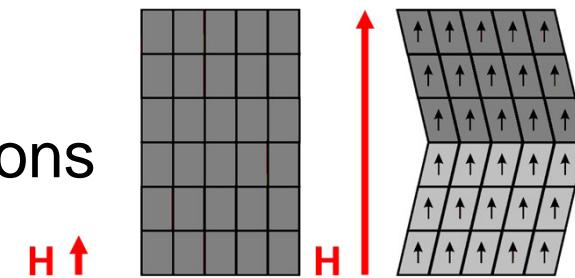


Magnetoelastic Materials

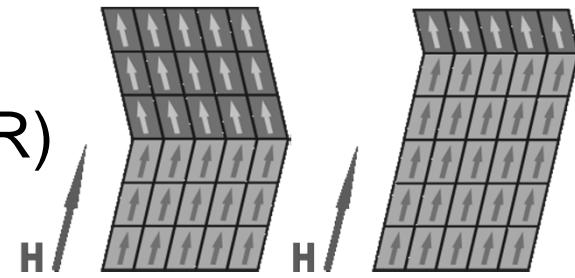
- Magnetostriiction



- Magnetically Induced Structural Transitions

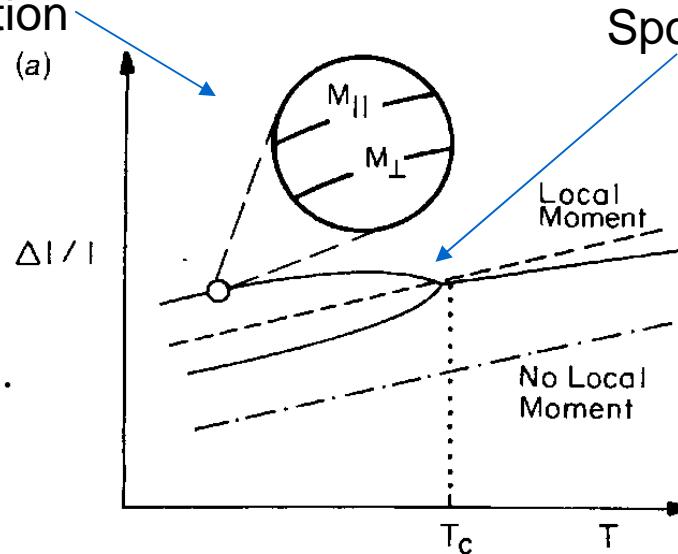


- Magnetically Induced Reorientation (MIR)



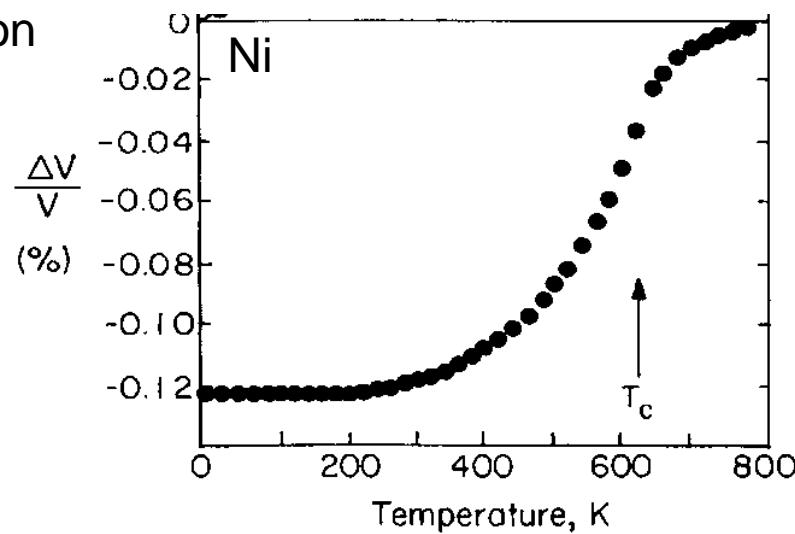
Magnetostriuctive effects

Anisotropic magnetostriiction

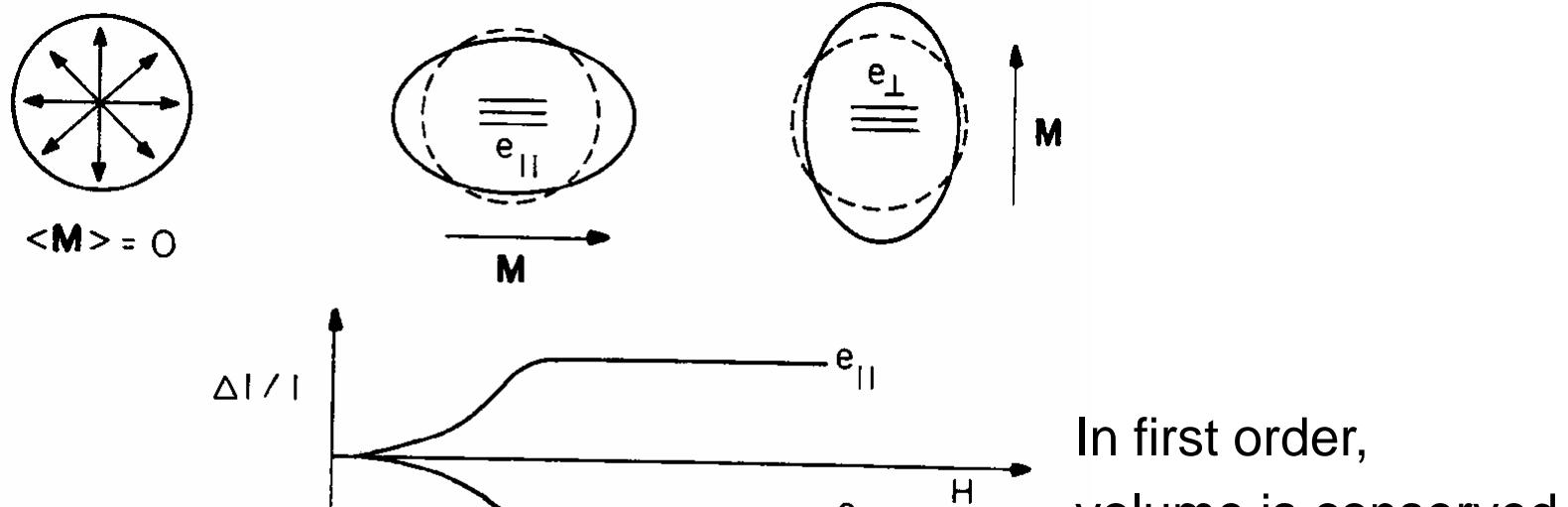


Spontaneous magnetostriiction

Volume magnetostriiction

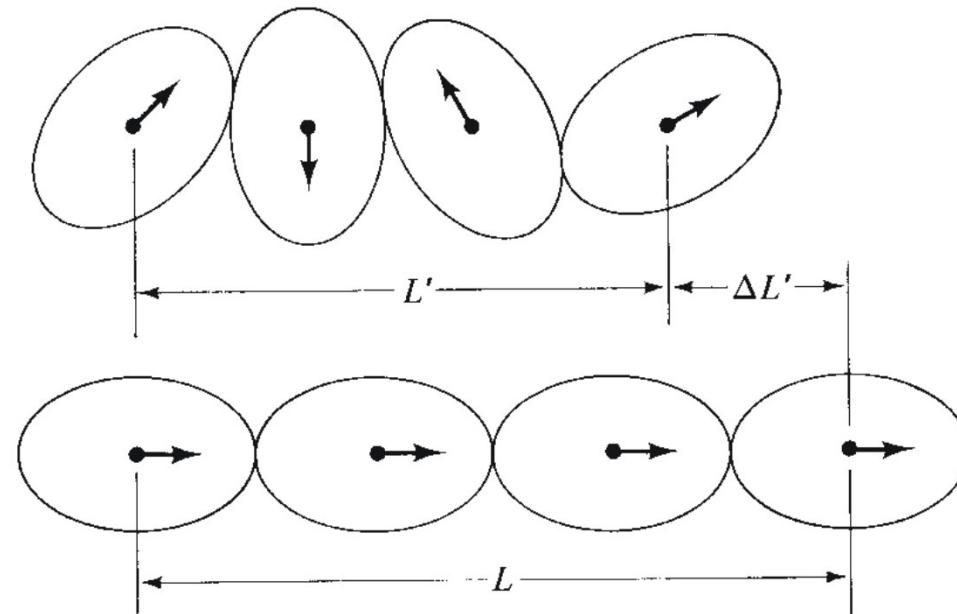


Anisotropic magnetostriiction



Saturation magnetostriiction λ_s
when all moments are aligned

Origin of magnetostriiction



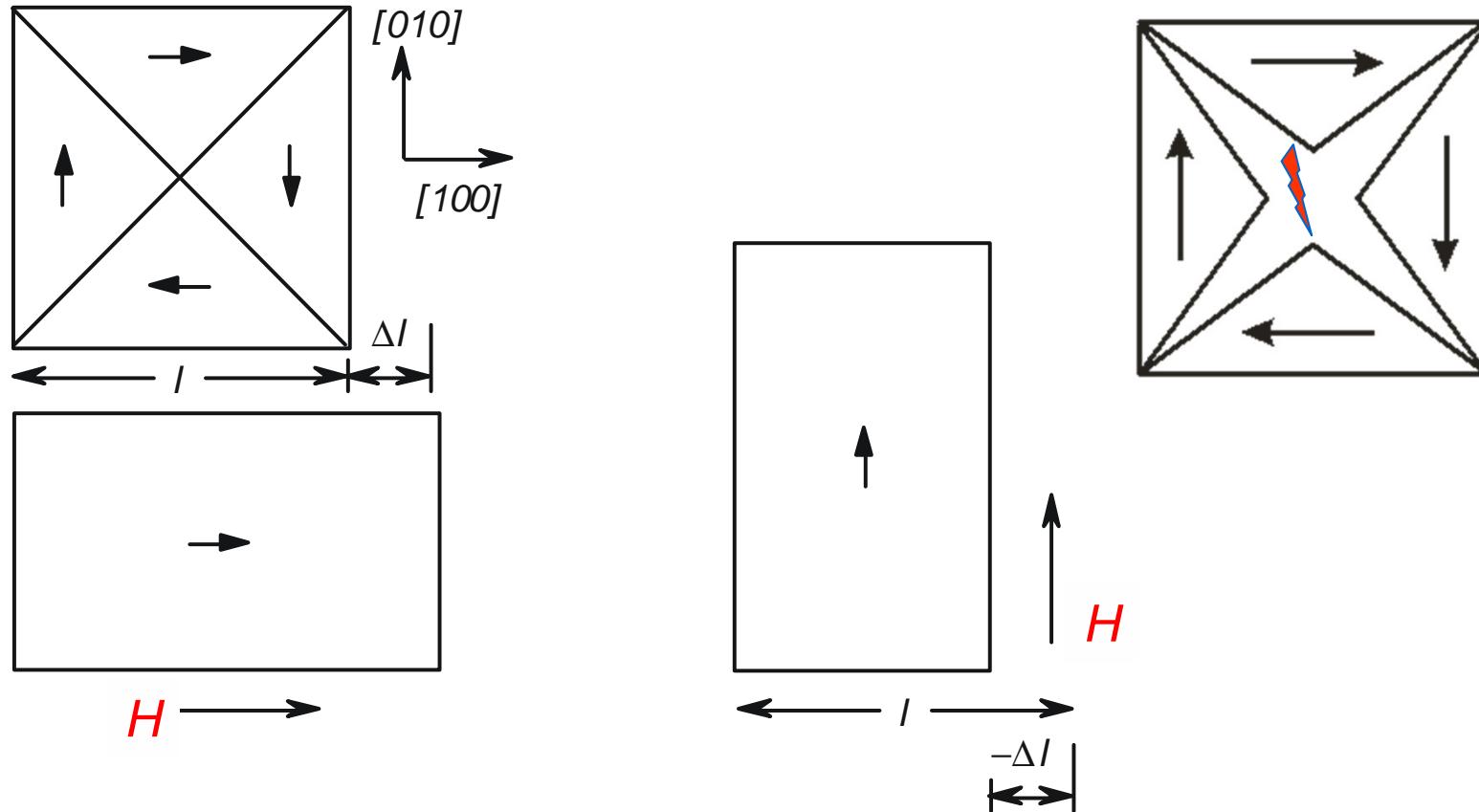
Below T_C :

Spin-Orbit coupling aligns orbits

Modifies distance between atoms (spontaneous magnetostriiction)

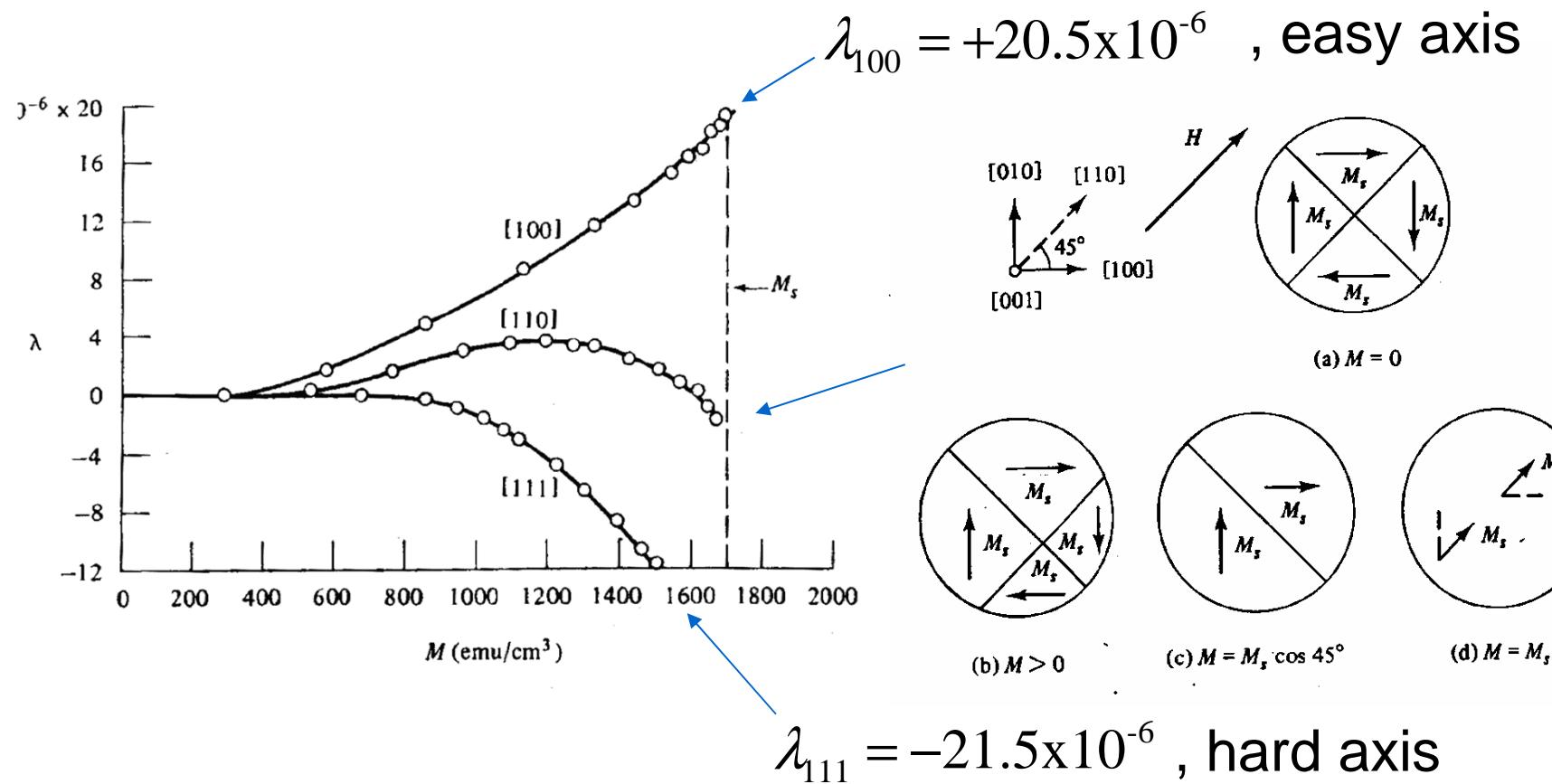
Magnetic field modifies direction (anisotropic magnetostriiction)

Magnetostriction and domains



- Ideal case:
 - Demagnetized state consists of all possible domains in equal fraction
 - $\lambda_S > 0$: Extension in field direction
 - $\lambda_S < 0$: Compression in field direction

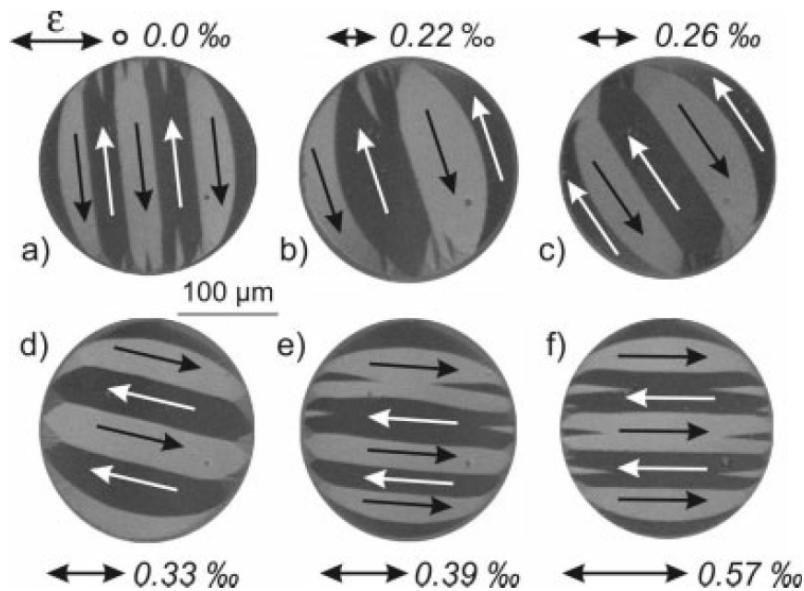
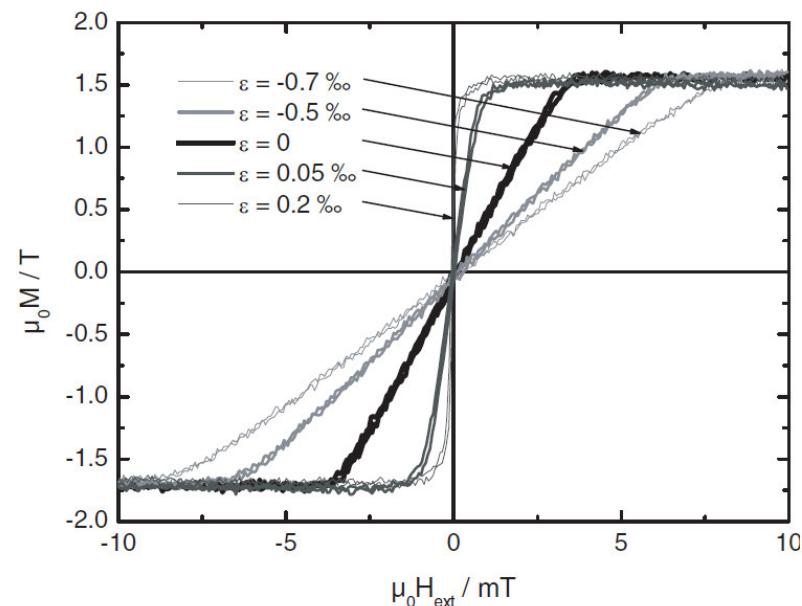
Magnetostriction of a Fe single crystal



- Complex behavior when domain wall motion and rotation is involved

Inverse magnetostriiction

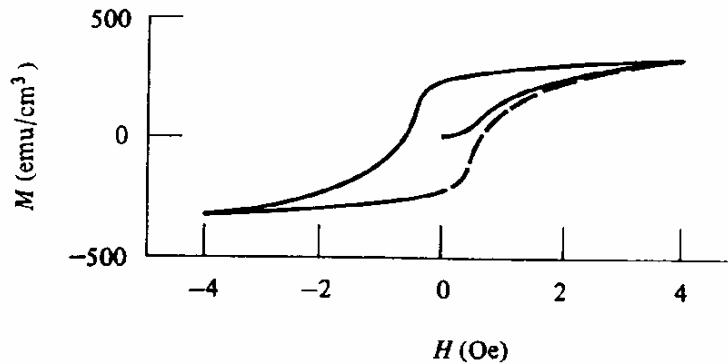
Straining of a 500 nm FeCoBSi film



- Stress induced anisotropy
- Easy axis aligns along strain direction

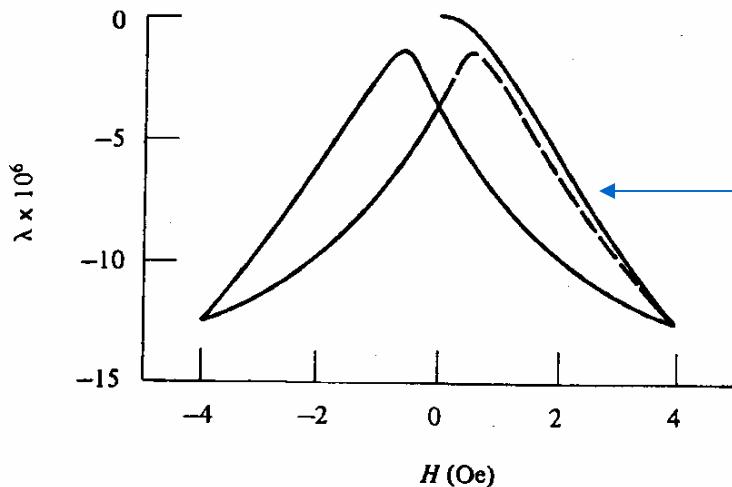
Applications of magnetostriction

Ni



Applications:

- Ultrasonic sound generators
- Microactuators + sensors



Symmetric curve
-> Frequency doubled

Best for applications:

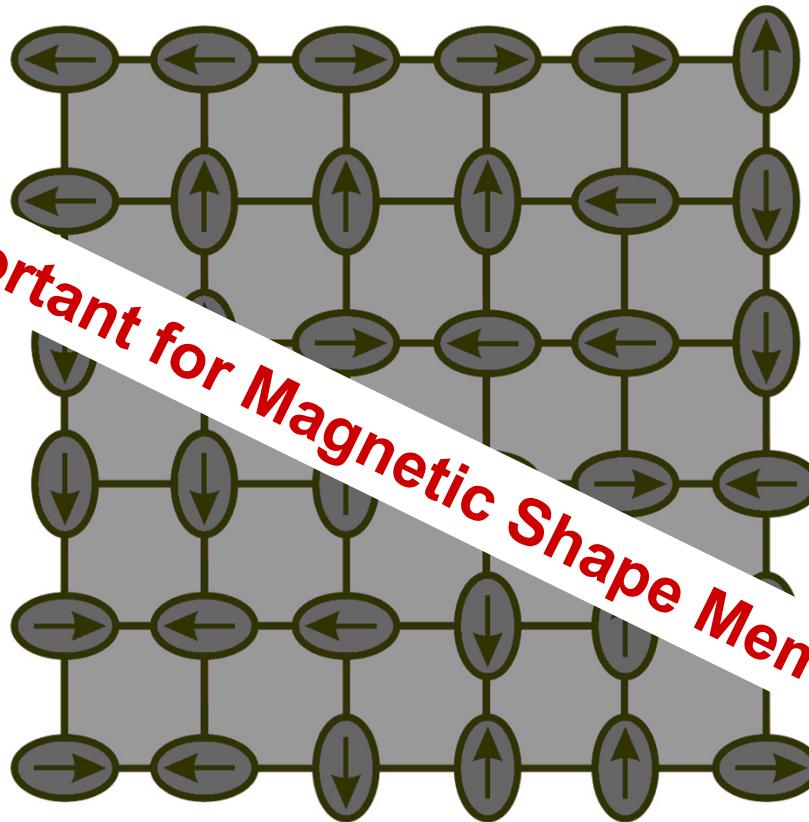
- Low hysteresis
- Bias field

Best materials:

- Terfenol-D (Dy,Tb)Fe₂: 0.24%
- Galfenol (Fe-Ga): 0.03 %

H .

- *Single ion anisotropy*

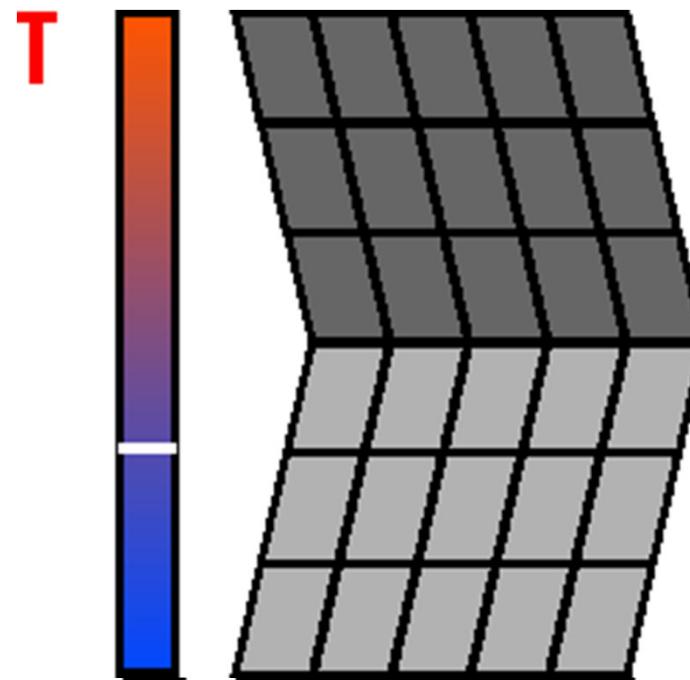


O. Heczko, J. Mag. Mag. Mat. 290-291 (2005) 846

- Strain < 0.24 %
 - + High frequency
 - + Low magnetic field

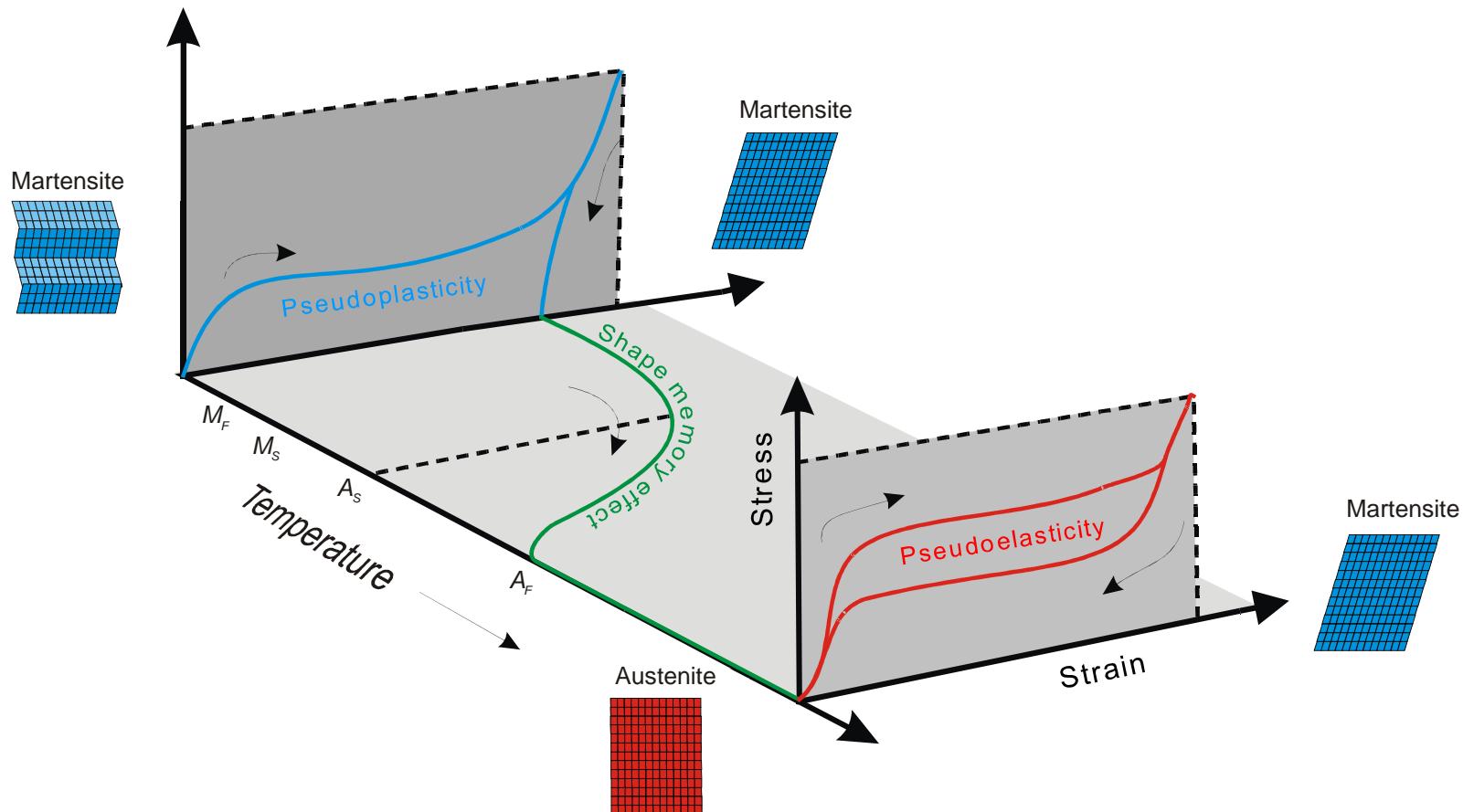
$T > T_M$:
Austenite
(high symmetry)

$T < T_M$:
Martensite
(low symmetry)

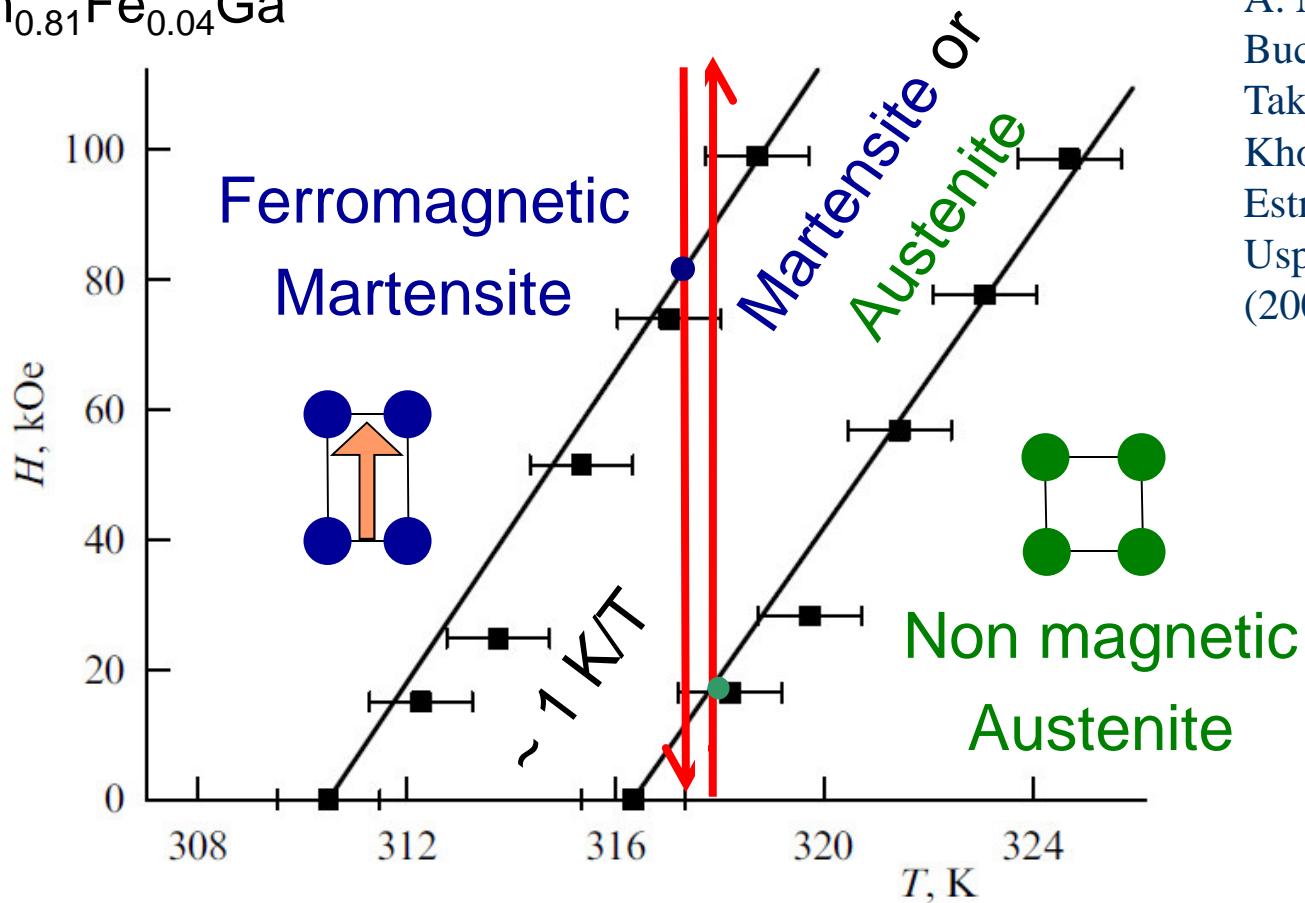


- No diffusion, reversible
- Twinned microstructure

- + Strain > 5%
- + High forces
- Low frequency



- Different trajectories can be used in shape memory materials
 - Pseudoelasticity
 - Pseudoplasticity
 - Shape memory effect

$\text{Ni}_{2.15}\text{Mn}_{0.81}\text{Fe}_{0.04}\text{Ga}$ 

A. N. Vasil'ev, V. D.
Buchel'nikov, T.
Takagi, V. V.
Khovailok, E. I.
Estrin, Physics
Uspekhi 46(6)
(2003) 559-588

- Modification of **structure** and shape by a magnetic field

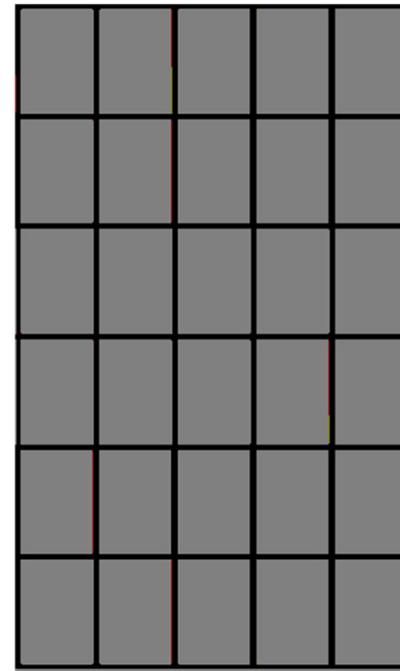
- High magnetic field $>> 1\text{ T}$
- Narrow temperature regime

Magnetic field favors
ferromagnetic phase

Clausius Clapeyron:

$$\frac{dT}{dH} = -\frac{\Delta J}{\Delta S}$$

H .

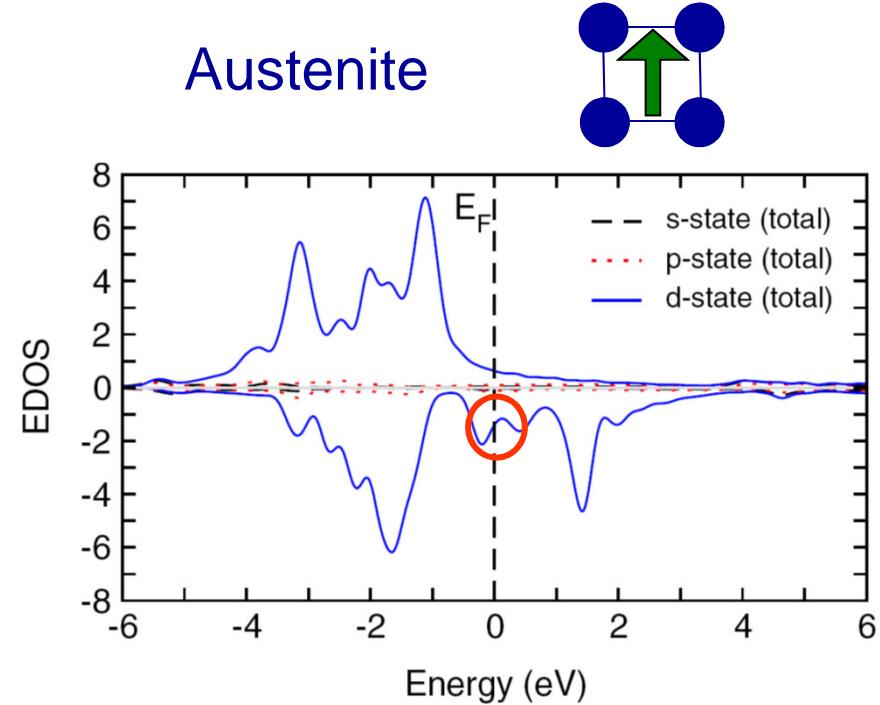
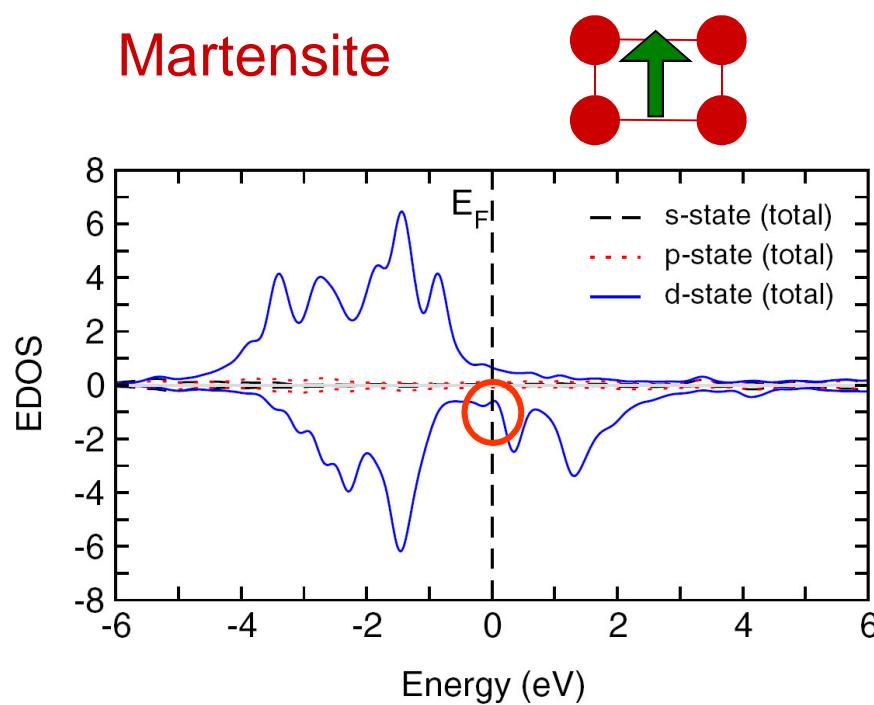


- Magnetic actuation
- First order structural transition
- Latent heat

+ Remote actuation

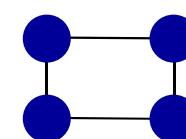
Ni₂MnGa

M. Gruner

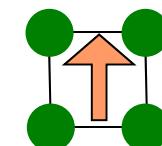
A3: P. Entel,
*U. Duisburg-Essen*UNIVERSITÄT
DUISBURG
ESSEN

- Austenite and Martensite are ferromagnetic
- Martensitic deformation allows to reduce energetically unfavorable high DOS at E_F

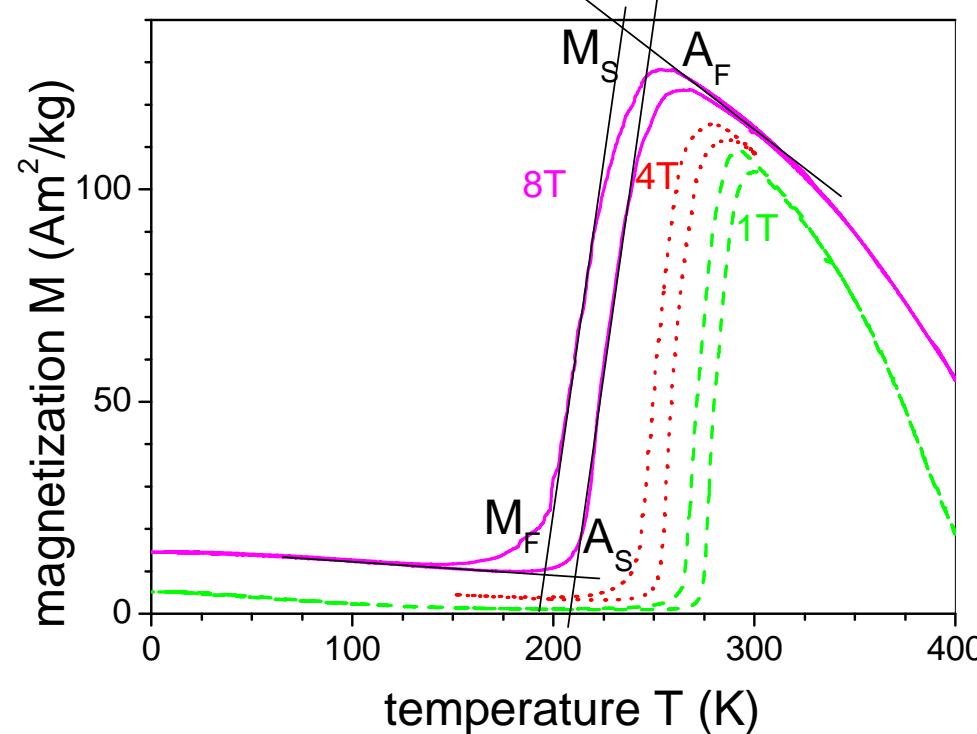
P. Entel et al. J. Phys. D: Appl. Phys. 39 (2006) 865

$\text{Ni}_{45}\text{Co}_5\text{Mn}_{36.7}\text{In}_{13.3}$ 

Nonmagnetic Martensite



Ferromagnetic Austenite



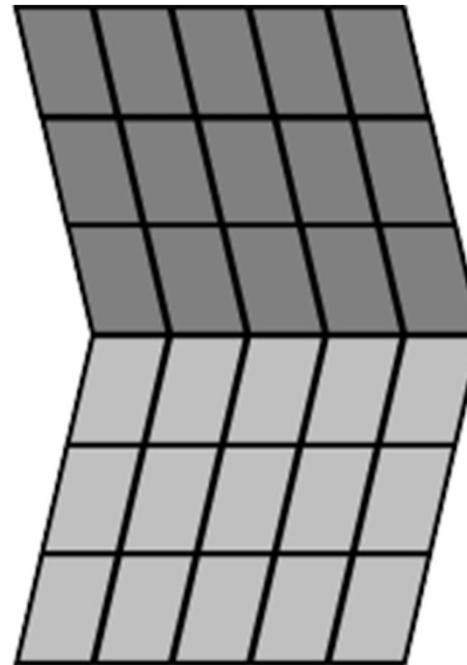
- Collapse of magnetisation by martensitic transition
- External field shifts martensitic transformation to lower temperatures

Magnetic field favors
ferromagnetic phase

Clausius Clapeyron:

$$\frac{dT}{dH} = -\frac{\Delta J}{\Delta S}$$

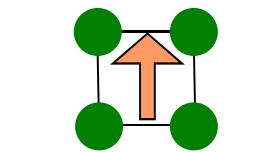
H .



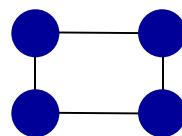
Negative $\Delta J \rightarrow H$ stabilizes austenite

Larger ΔJ by *metamagnetic transition* (not close to T_C)
→ Lower magnetic field required

$\text{Ni}_{45}\text{Co}_5\text{Mn}_{36.7}\text{In}_{13.3}$

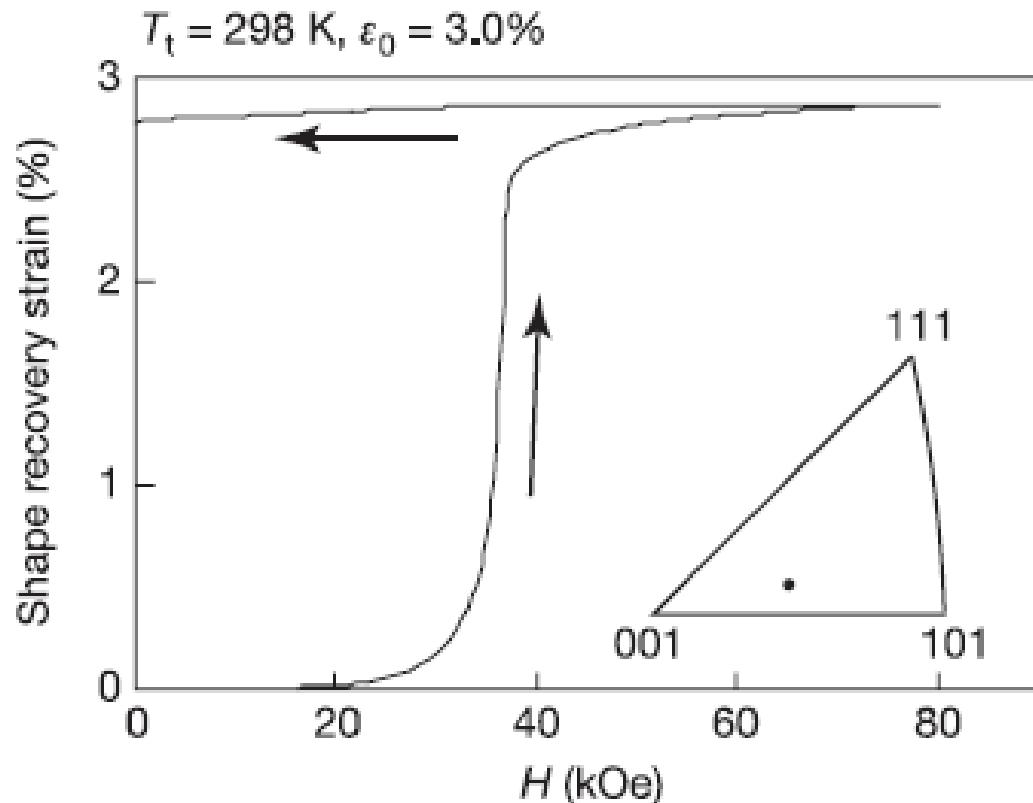


High J
Austenite



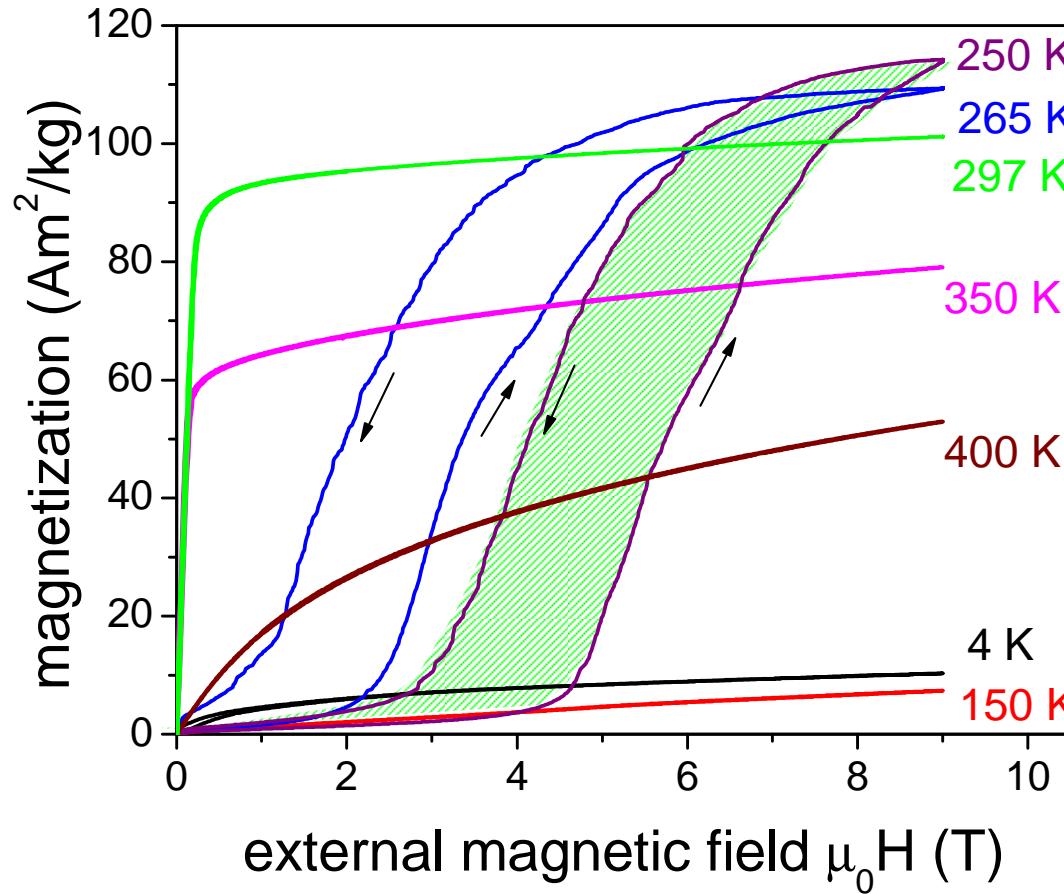
Low J
Martensite

- Hysteresis may inhibit reversibility



R. Kainuma et al.
Nature 439 (2006) 957

- + Strain $\sim 3\%$
- + Hysteresis losses?
- + No anisotropy needed



A.N. Vasiliev, O. Heczko,
O.S. Volkova, T.N.
Vasilchikova, T.N.
Voloshok, K.V. Klimov,
W. Ito, R. Kainuma, K.
Ishida, K. Oikawa, and S.
Fähler, J. Phys. D: Appl.
Phys. 43 (2010) 055004

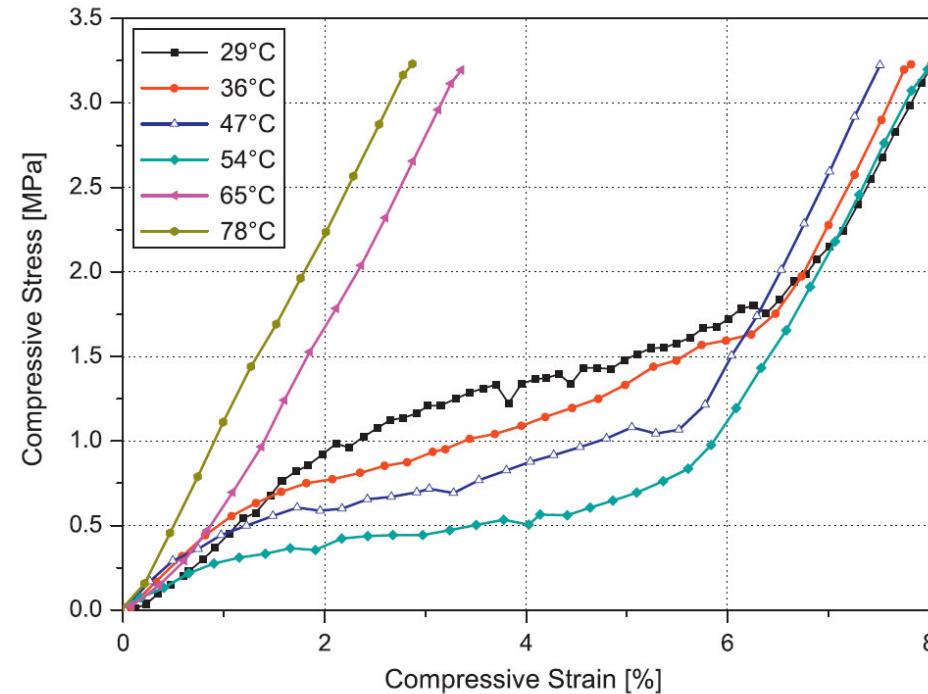
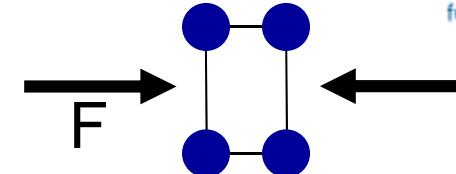
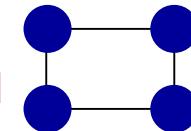
- Energy input: $\int_0^{H_s} \Delta J dH$ (hatched area)
- Can be increased by increasing H
- But: In this case no external work was performed, hence
Energy input = Hysteresis loss

Ni-Mn-Ga

K. Rolfs, A. Mecklenburg

B2: R. Schneider

5M

At const $T < T_M$ 

- Easy movement of twin boundaries (~ MPa)

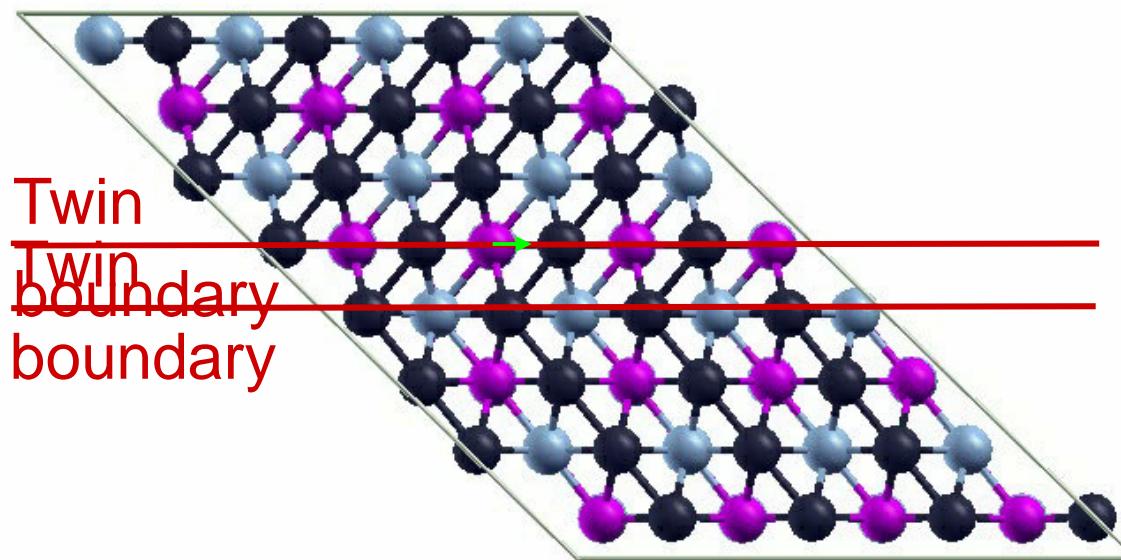
- Little pinning of twin boundaries at defects

NM Ni-Mn-Ga

M. Gruner

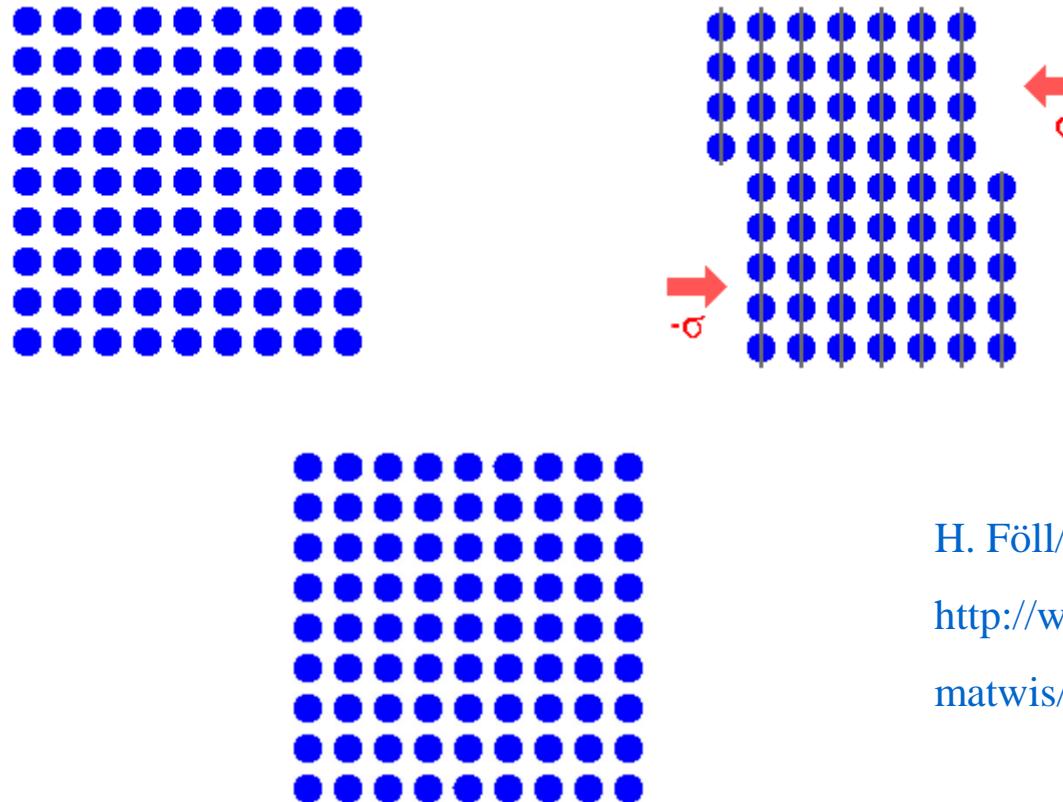
A3: P. Entel,
U. Duisburg-Essen

UNIVERSITÄT
DUISBURG
ESSEN



- Only small movements of atoms required
- But a collective movement would require to move 10^{23} atoms simultaneously...

- How to deform a crystals by external stress?



H. Föll/ U. Kiel

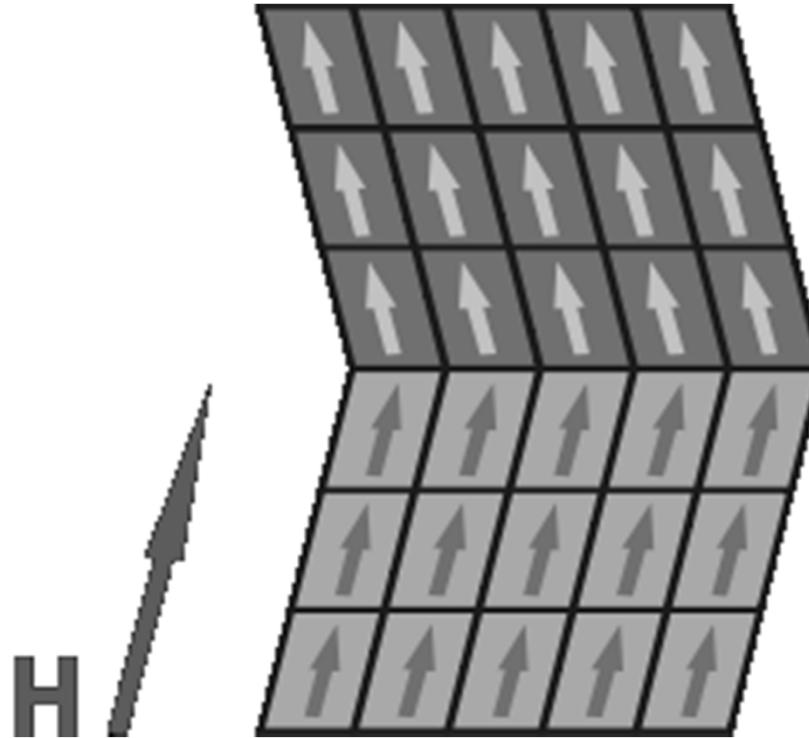
<http://www.tf.uni-kiel.de/>

matwis/amat/def_en/index.html

- Dislocations allows to move line defect instead of a complete plane

Twin boundary movement

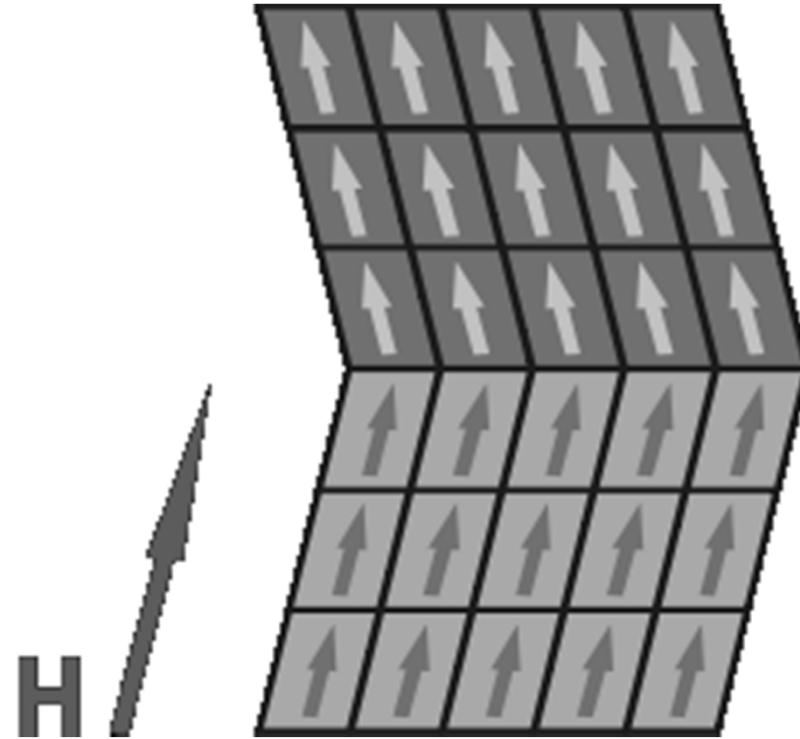
No phase transition,
affects only microstructure



Requires:

- Non-cubic phase
- High magnetocrystalline anisotropy
- Easily movable twin boundary

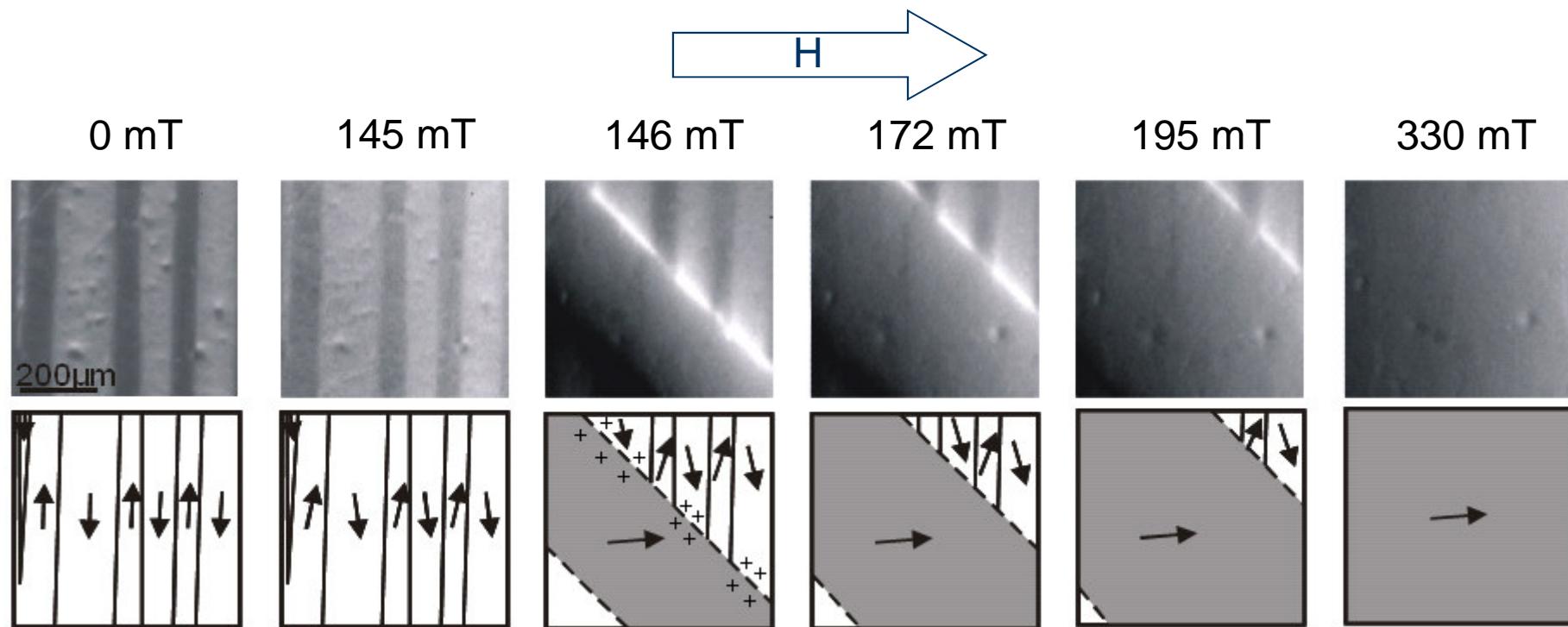
++ Strain up to 12 %
+ High frequency



- Rotation of magnetization must be avoided
 - ⇒ high magnetocrystalline anisotropy needed
 - High H_A
 - Switching field $H_S < H_A$

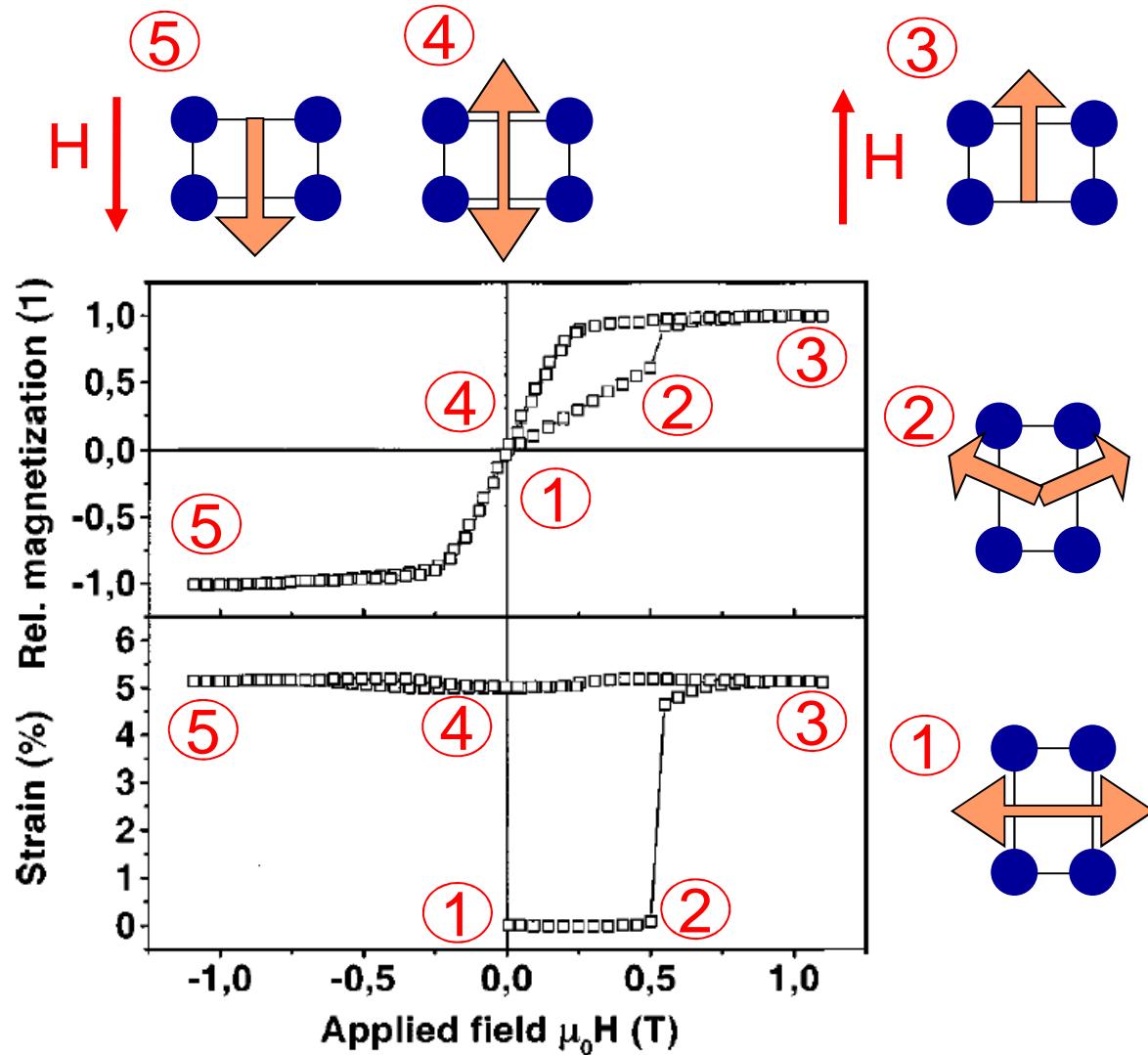
5M Ni-Mn-Ga

Y. W. Lai

B1: J. McCord, R. Schäfer
IFW Dresden

- Magnetic field moves twin boundary instead of rotating magnetization

Y. W. Lai, N. Scheerbaum, D. Hinz, O. Gutfleisch, R. Schäfer, L. Schultz, J. McCord,
App. Phys. Lett. 90 (2007) 192504

Ni-Mn-Ga
5M

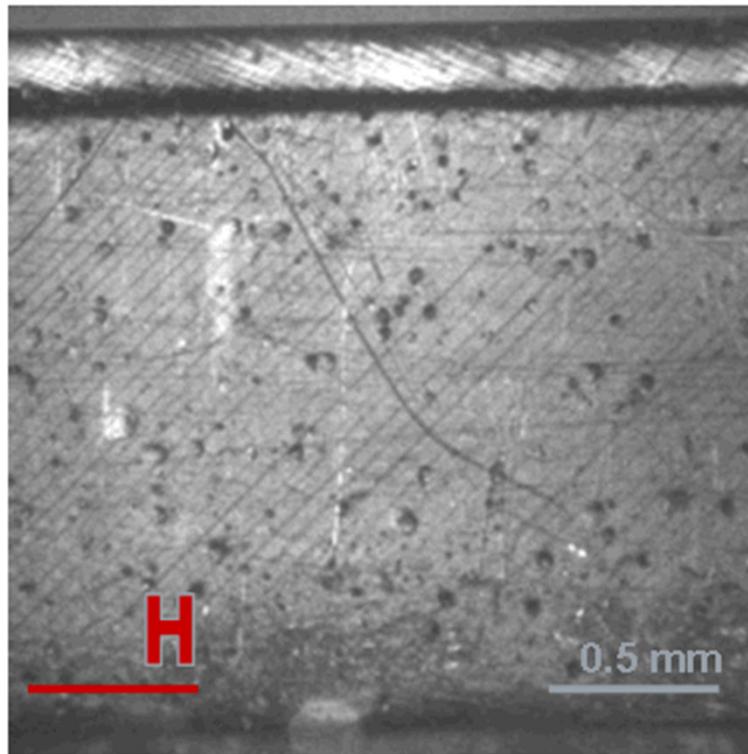
O. Heczko, L. Straka, N.
Lanska, K. Ullakko, J.
Enkovaara, J. Appl. Phys.
91(10) (2002) 8228

○ moderate switching
field $H_S < 1$ T

5M Ni-Mn-Ga

Y. W. Lai

B1: J. McCord, R. Schäfer
IFW Dresden

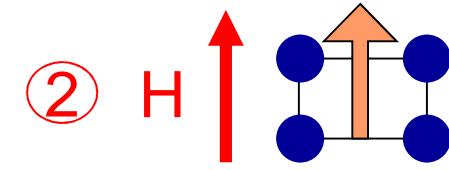
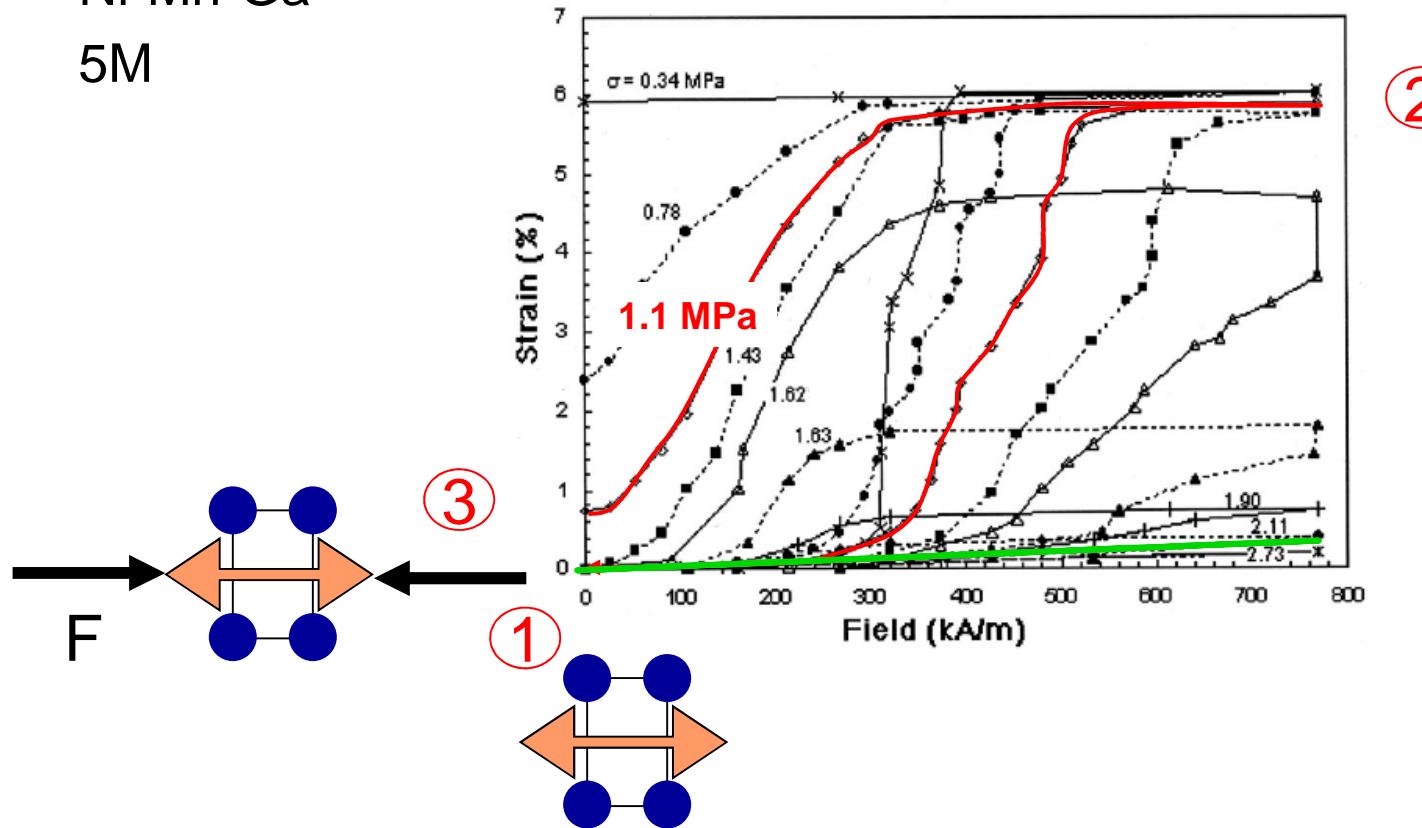


} 6...10 % strain

© Ryan Lai & Jeffrey McCord, IFW Dresden

Restoring force by spring

Ni-Mn-Ga
5M



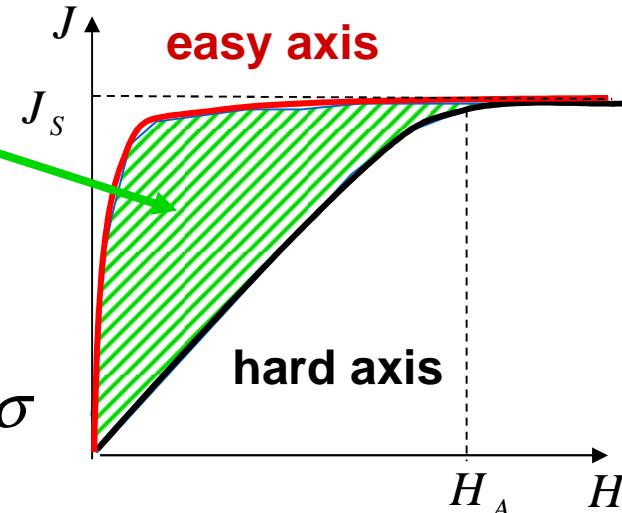
Blocking stress
~2 MPa

S. J. Murray, M. Marioni, S. M. Allen, R. C. O'Handley, T. A. Lograsso, Appl. Phys. Lett. 77(6) (2000) 886

- low blocking stress
- low forces

Gain of magnetic energy density by reorientation

$$w_{\max} = k_U \left(\approx \frac{1}{2} H_A J_S \right)$$



Mechanical work density $w = \sigma \varepsilon_0$

Maximum internal and external stress : σ

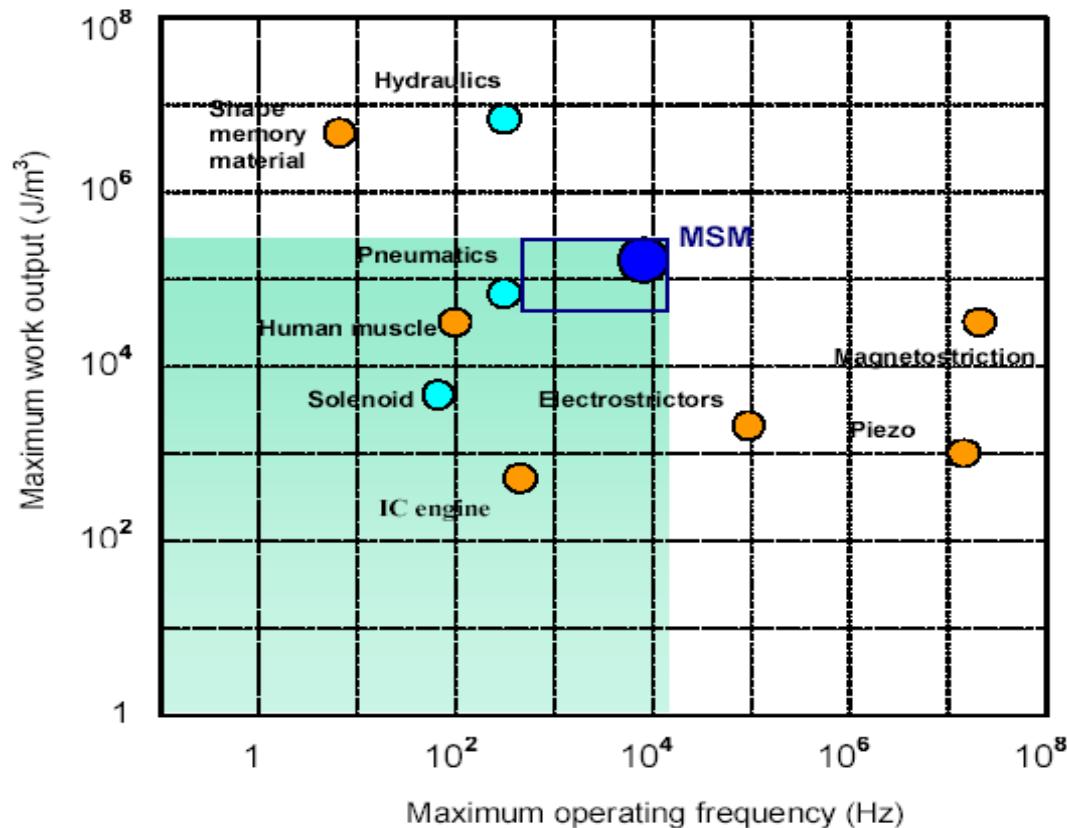
Maximum strain : $\varepsilon_0 = 1 - \frac{c}{a} \approx 6 \dots 10\%$

Balance

$$\sigma \varepsilon_0 = k_U$$

$$\Rightarrow \sigma = \frac{k_U}{\varepsilon_0} \approx 2 \text{ MPa}$$

- low blocking stress
- low forces
- + high work output



www.intellimat.com

- Strain up to 10%
- High frequency possible
- High specific work output
- Low forces ~ MPa
- Switching fields 0.1 - 1 T

Refers only to the material, not to the complete system!

Intrinsic properties (composition, phase)

- High martensitic transformation temperature \Rightarrow high application temperature
- High magnetocrystalline anisotropy \Rightarrow avoids rotation of magnetization
- High magnetization \Rightarrow efficient coupling to external field
- Maximum strain $\varepsilon_0 = 1 - c/a$

Extrinsic properties (microstructure, texture)

- High strain $\varepsilon < \varepsilon_0$
- Low switching field $H_S < H_A$
- Easily moveable twin boundaries \Rightarrow rubber like behavior

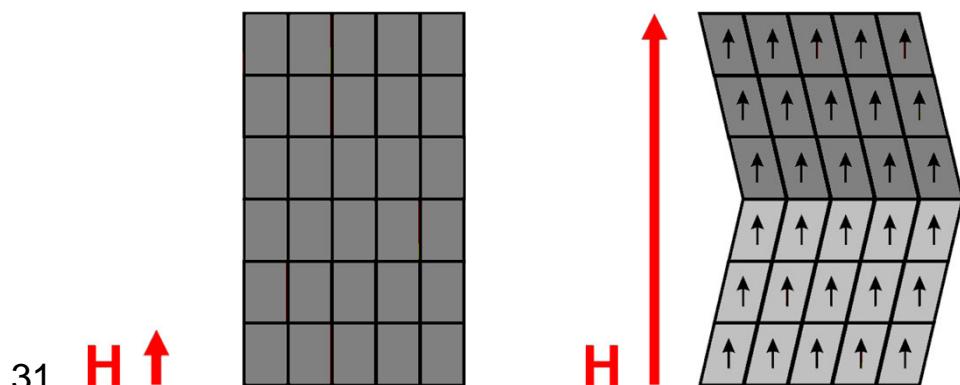
Aim: high strain in low magnetic fields

Magnetically Induced Martensite/Austenite (MIM/MIA)

- + Little constraints on microstructure
- + No magnetocrystalline anisotropy needed

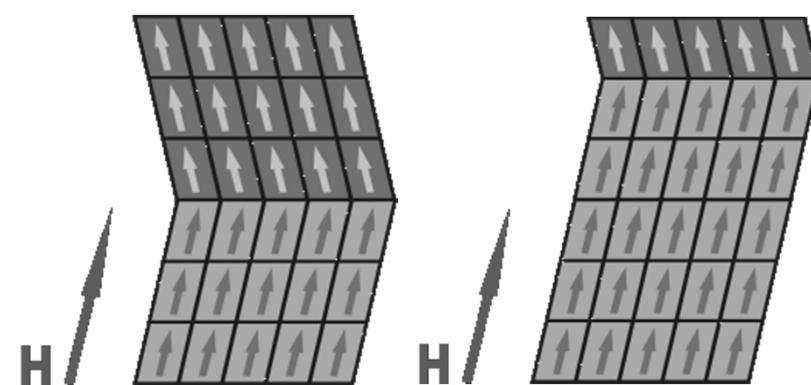
Work input increases with H

- High fields > 1 T
- Works only at the vicinity of martensitic transformation
- Magnetocaloric effect inhibits high frequency

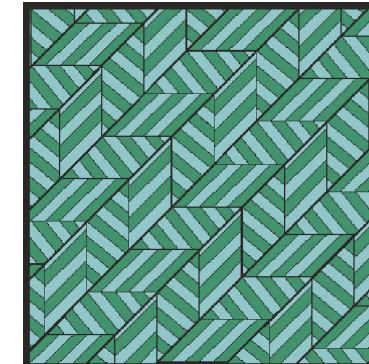
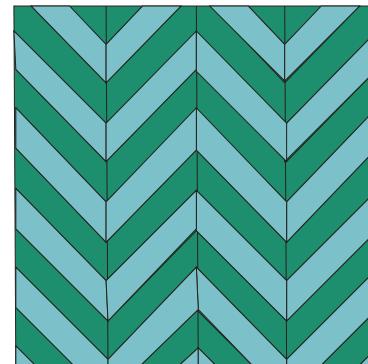


Magnetically Induced Reorientation (MIR)

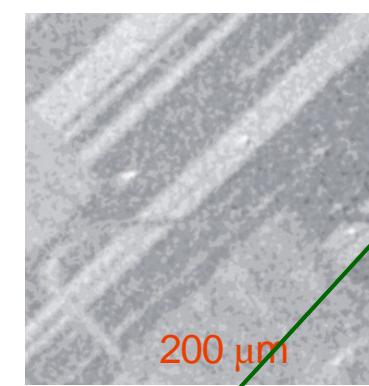
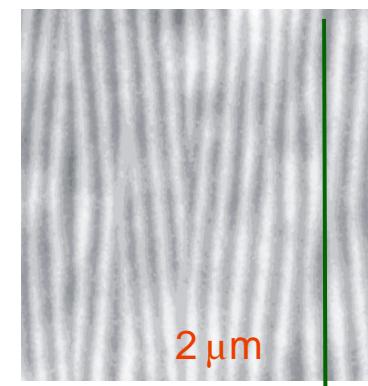
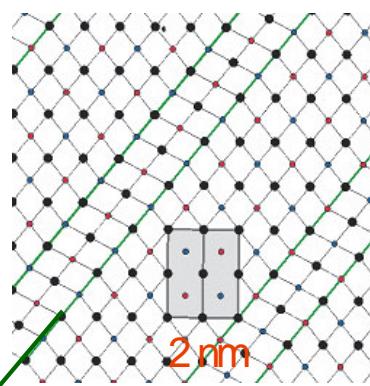
- Rubber like behavior needed
- High magnetocrystalline anisotropy
- Low forces
- + Moderate fields < 1 T
- + Works below martensitic transformation
- + High frequency (kHz) possible



A. L. Roytburd, Phase Transitions 45 (1993) 1



- Epitaxial Ni-Mn-Ga films

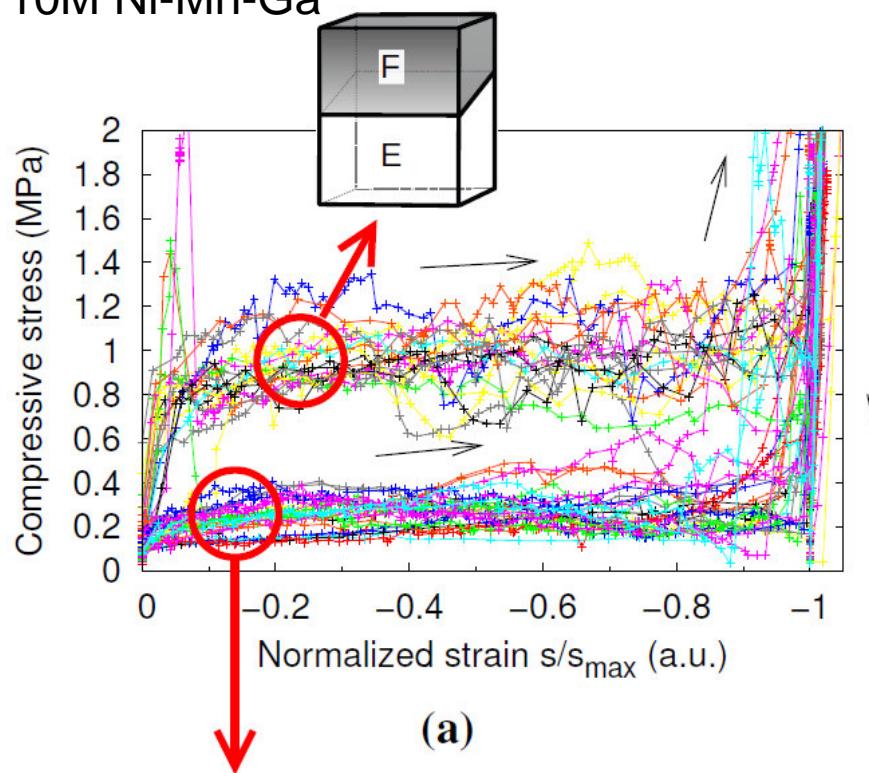


Primary TB

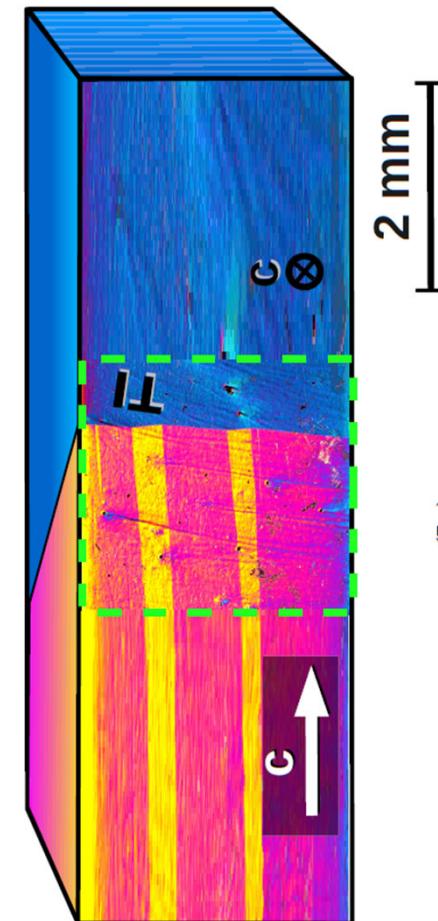
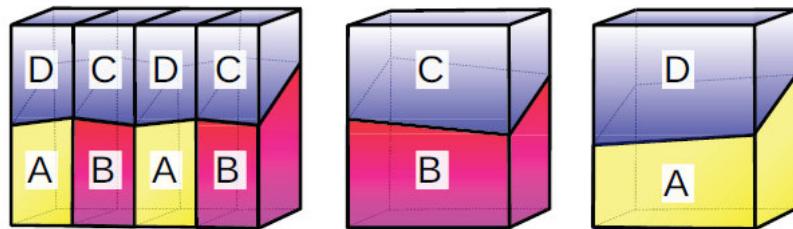
Mesoscopic
TB

Macroscopic
TB

10M Ni-Mn-Ga



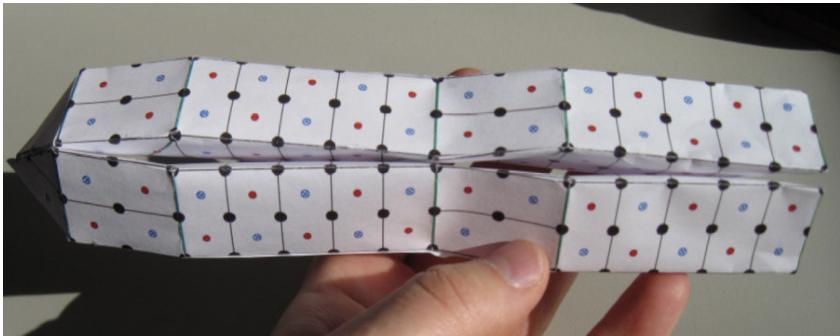
- ~1 MPa for type I TB



- ~0.2 MPa for type II TB

There are two ways to form mesoscopic twin boundaries:

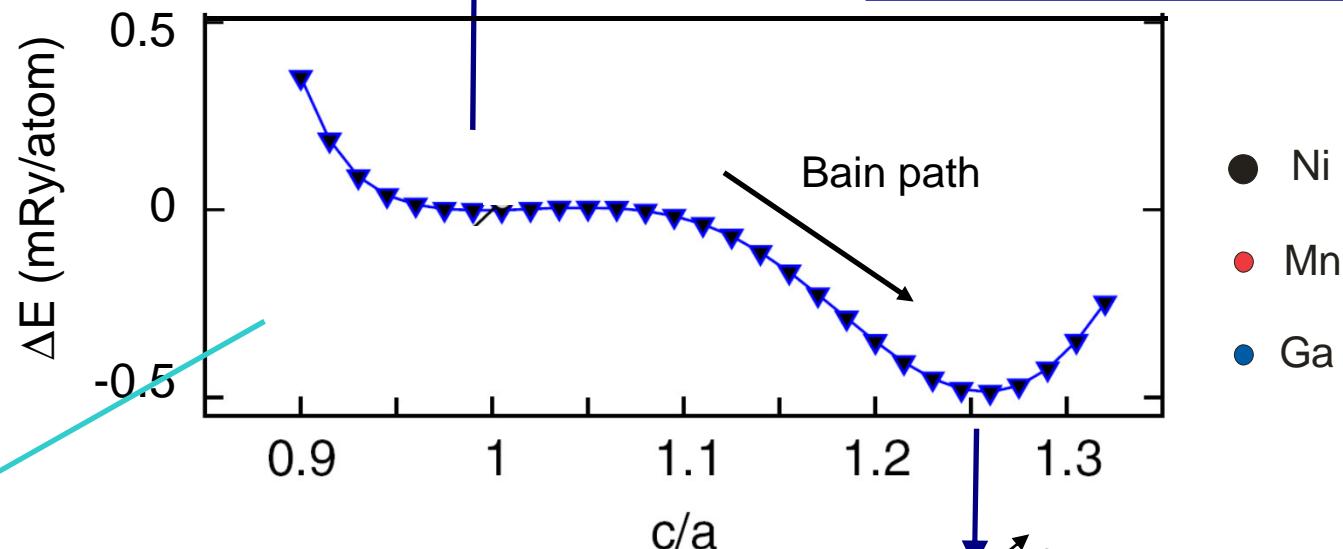
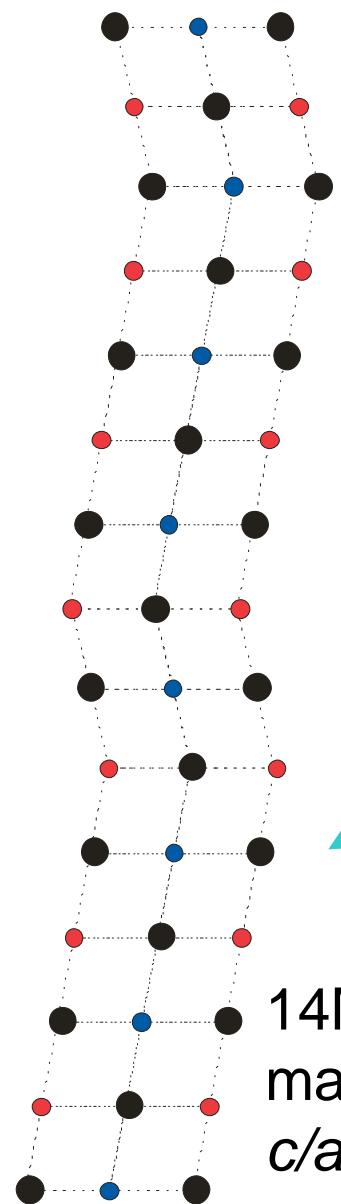
Type I



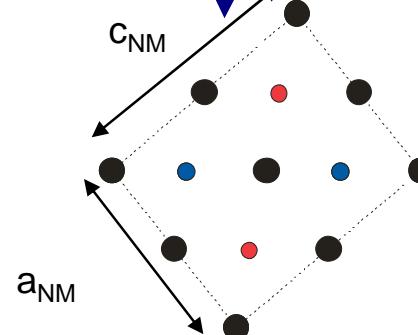
Type II



What is the origin of type I and II twin boundaries?

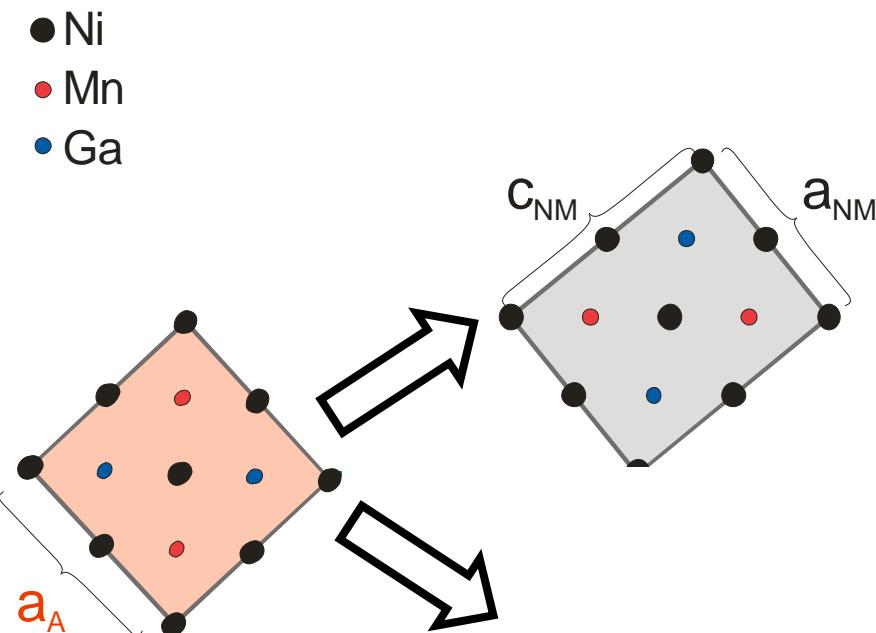


Tetragonal
NM martensite
 $c/a \approx 1.25$



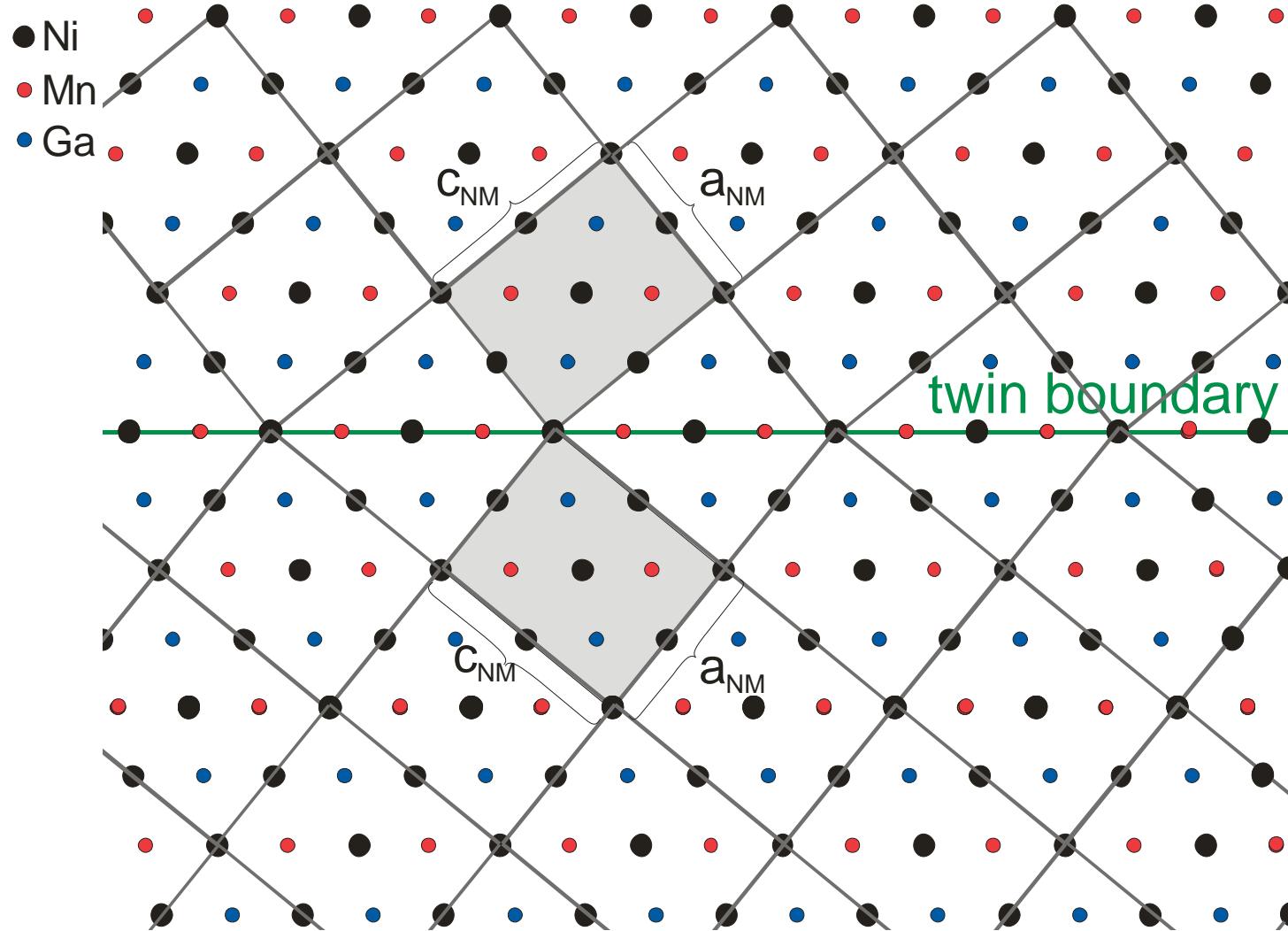
UNIVERSITÄT
DUISBURG
ESSEN

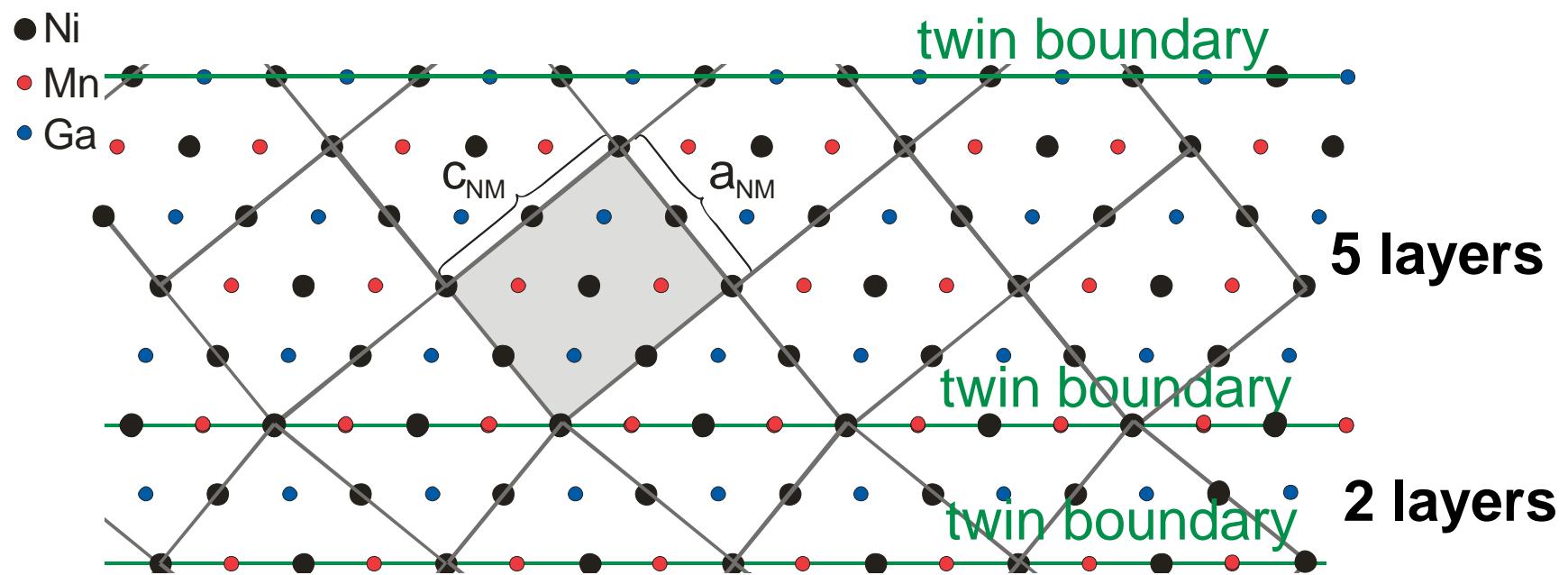
A3: P. Entel,
U. Duisburg-Essen

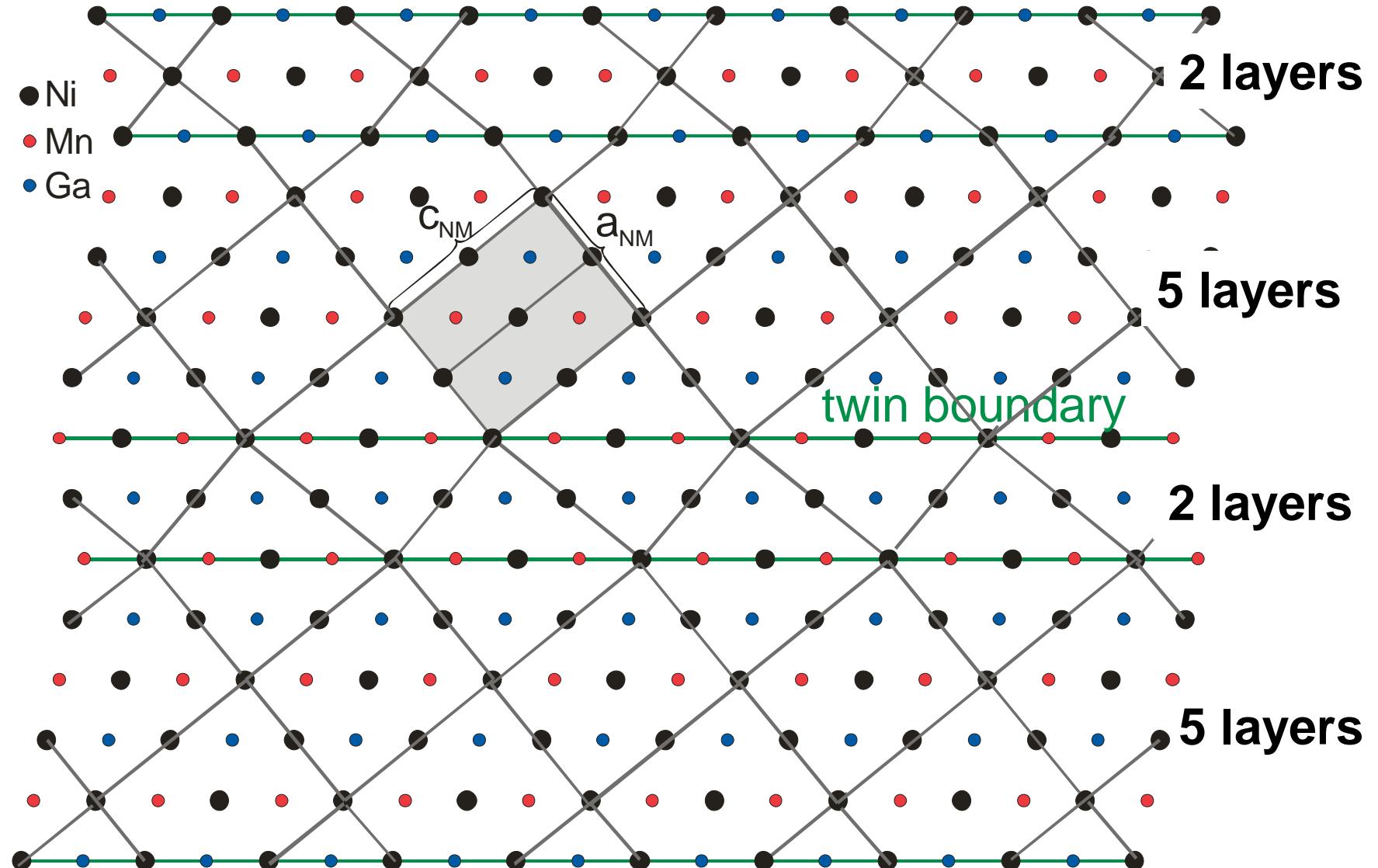


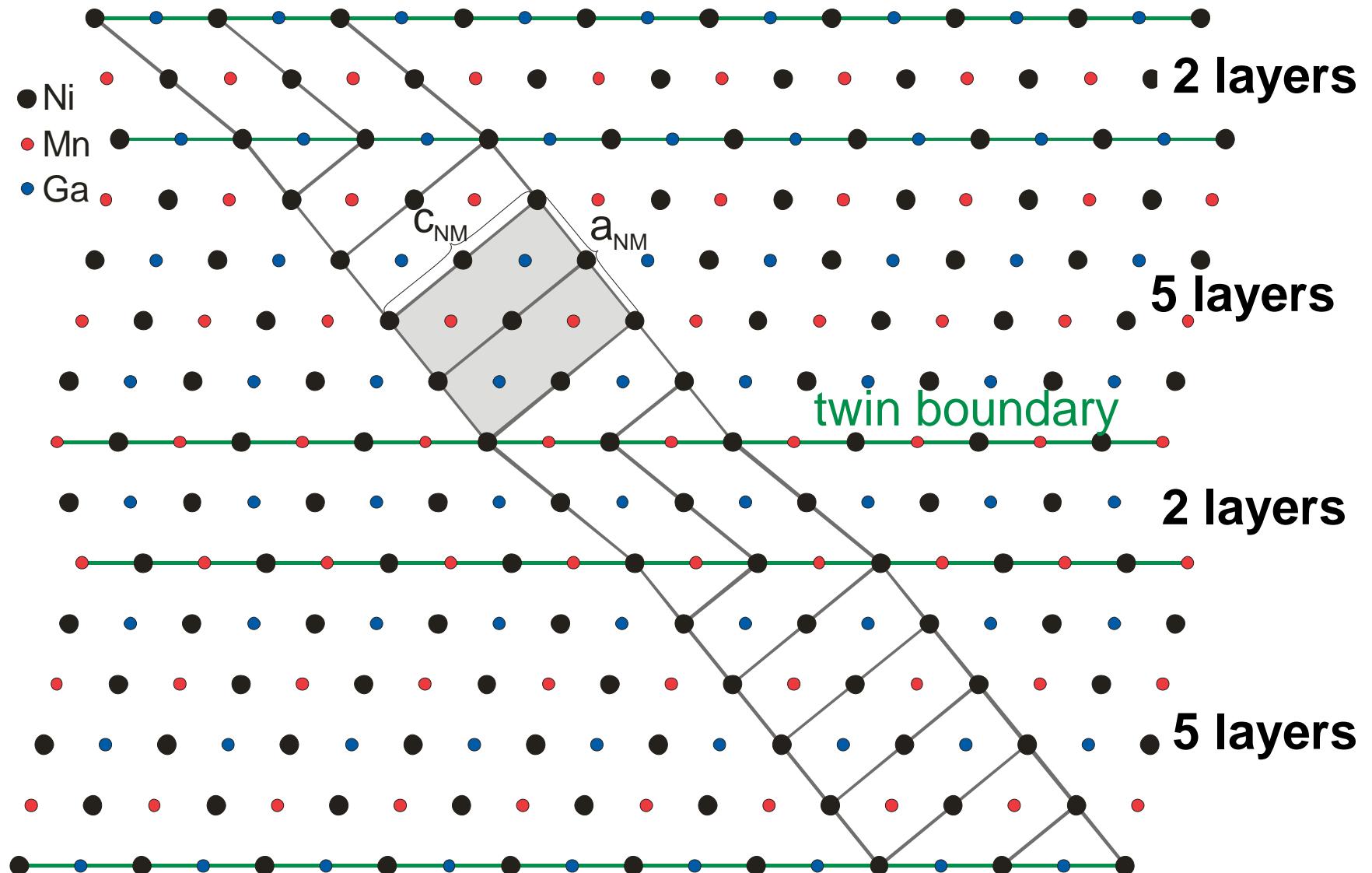
Austenite

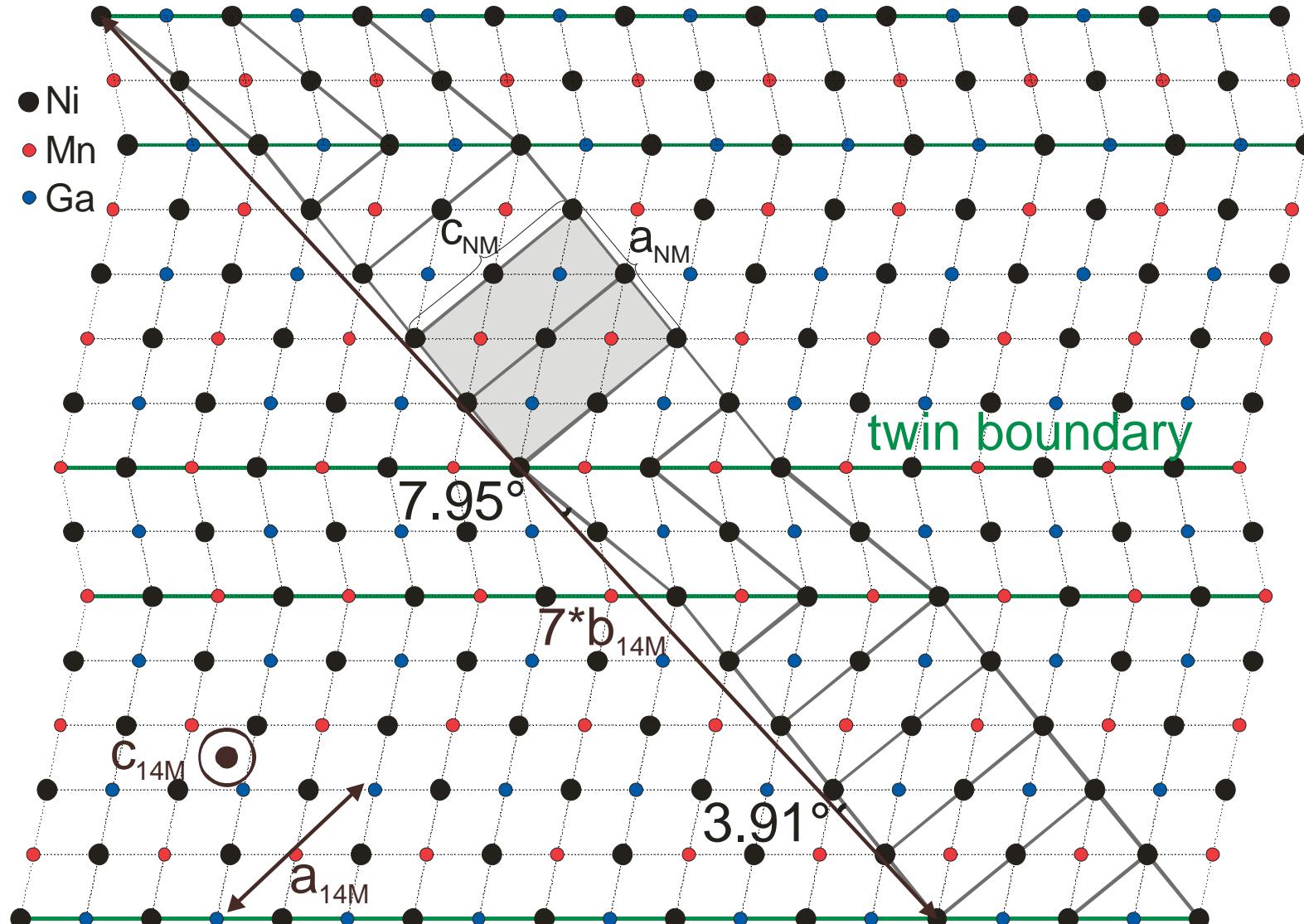
Tetragonal Martensite
(NM)

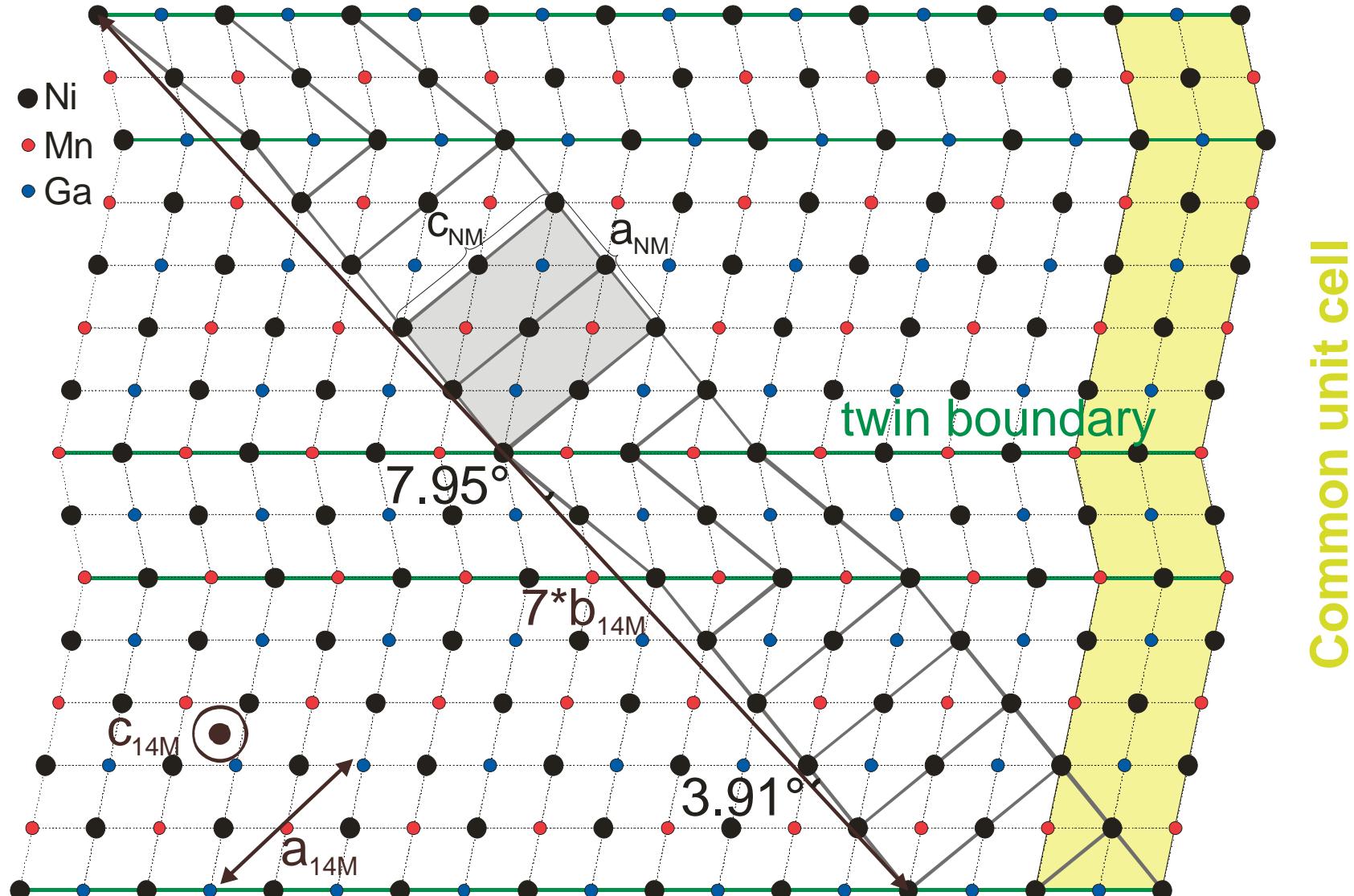


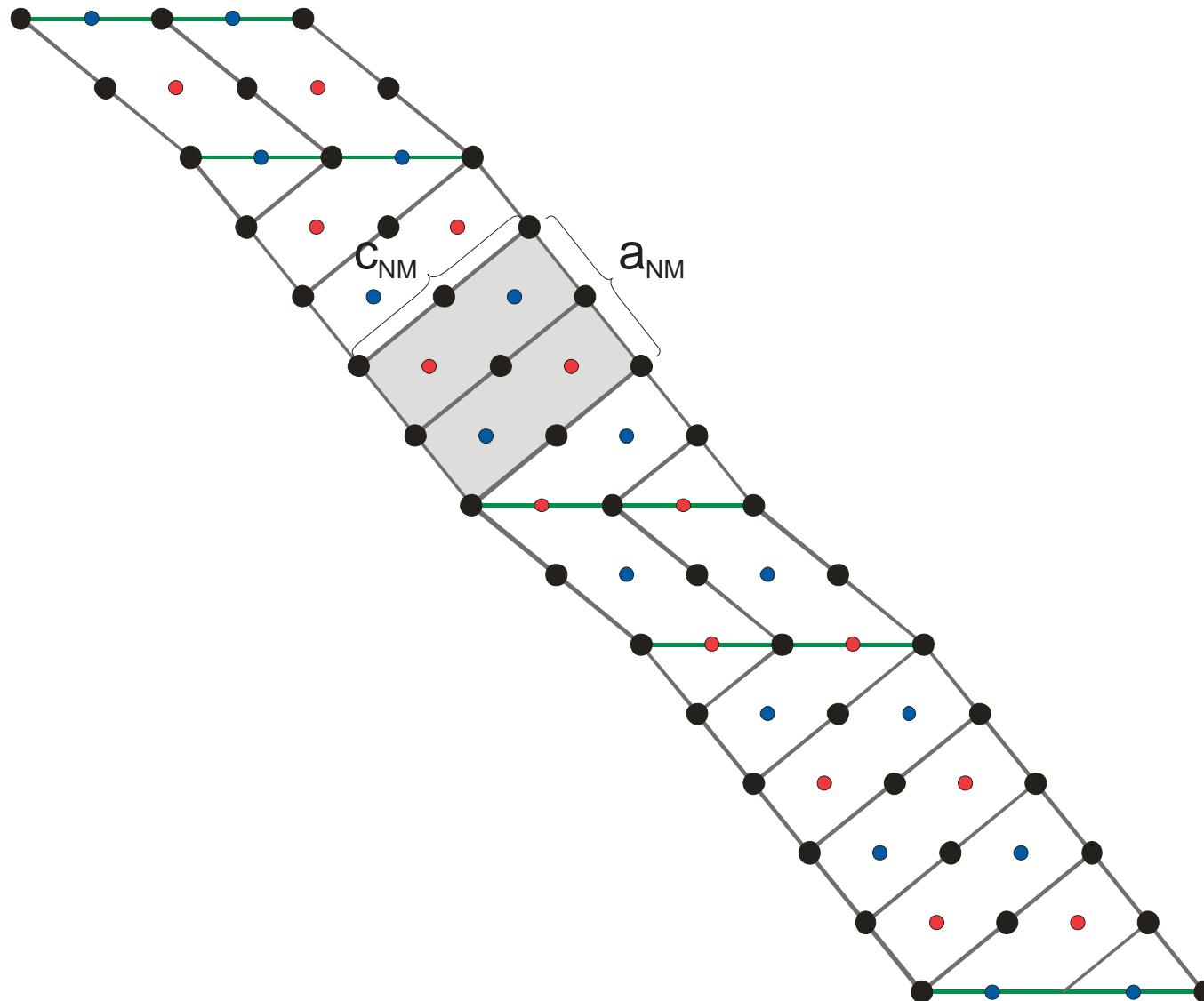


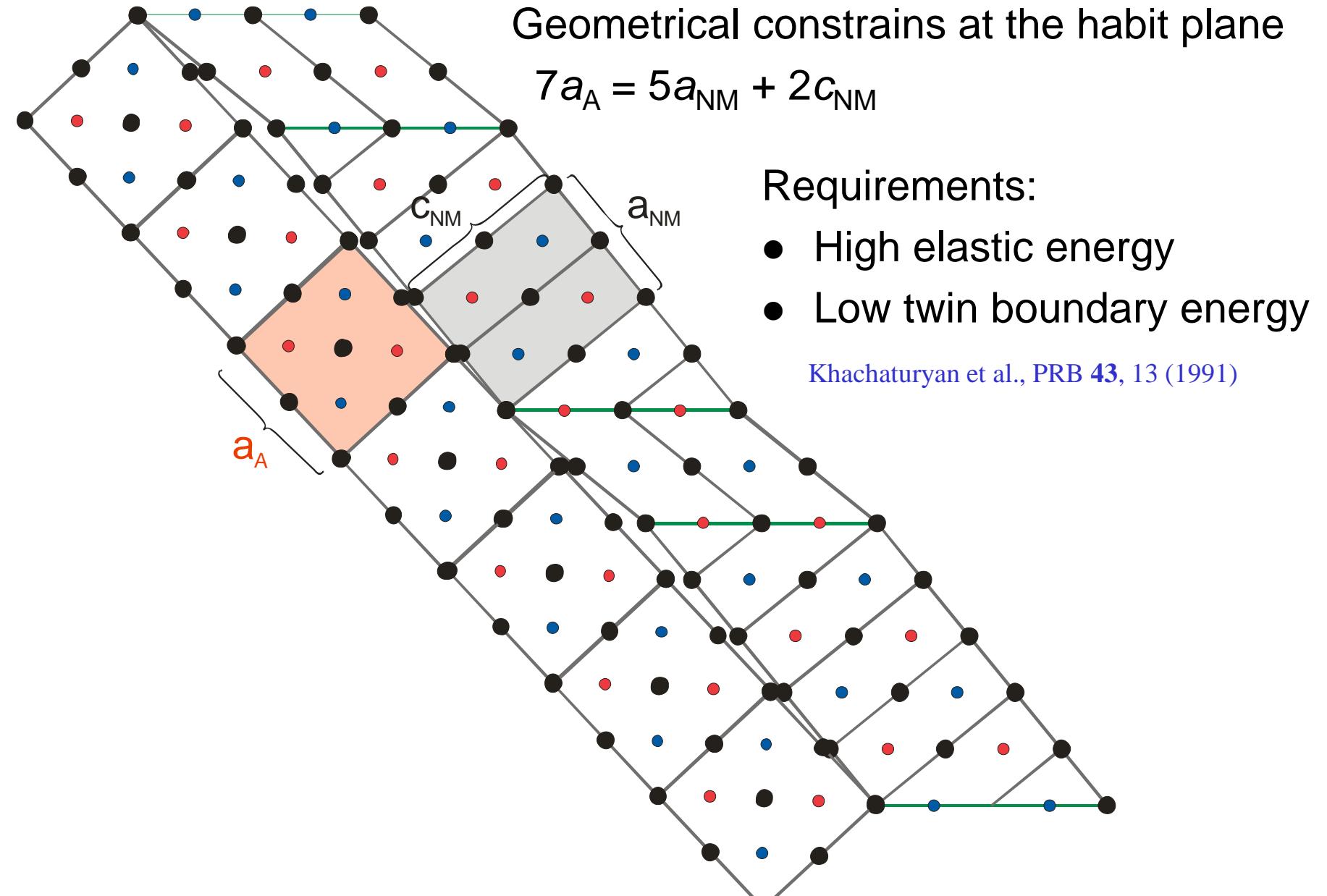


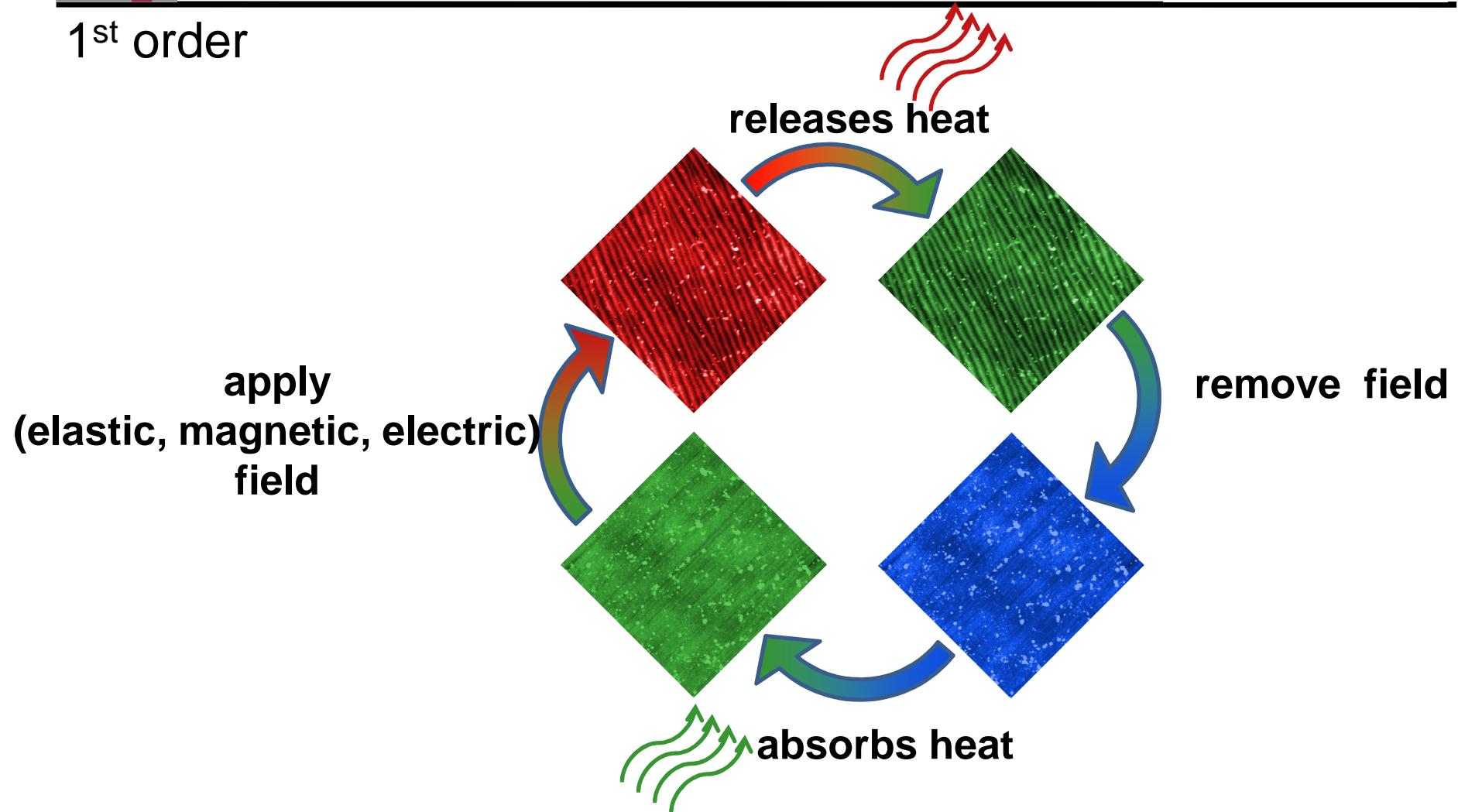






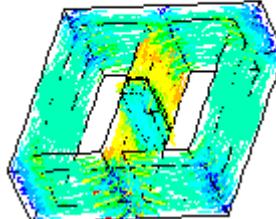




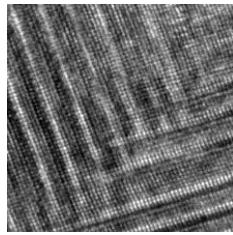
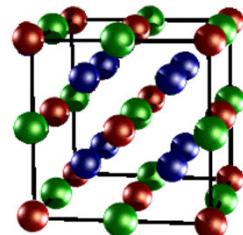
1st order

$$\Delta G = \Delta U - T\Delta S - p\Delta V + H\Delta M - \sigma\Delta\varepsilon + E\Delta P$$

applications

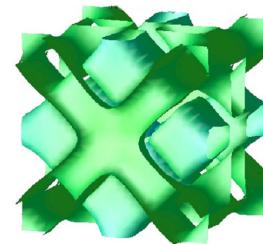


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atomic scale

fundamentals



micro-structure

www.MagneticShape.de

Further reading

- B. D. Cullity, C. D. Graham, *Introduction to Magnetic Materials*, 2nd Ed. Wiley, (2009), Chapter 8: *Magnetostriction and the effects of stress*
- É. Du Trémolet de Lacheisserie, D. Gignoux, M. Schlenker, *Magnetism – Fundamentals*, Kluwer (2003), Chapter 12: *Magnetoelastic effects*
- Special Issue: *Magnetic Shape Memory Alloys*, Adv. Eng. Mat. 14(8) (2012)
- A brief introduction on magnetic shape memory alloys with animated gifs:
<http://www.MagneticShape.de/funktionsprinzip.html>
- O. Heczko, N. Scheerbaum, and O. Gutfleisch, *Magnetic Shape Memory Phenomena* (Ch. 14), in J. P. Liu, E. Fullerton, O. Gutfleisch, and D.J. Sellmyer (eds), *Nanoscale Magnetic Materials and Applications*, Springer Science, 399 (2009).